

21V to 60V_{IN}, 150W ZVS Buck-Boost Regulator

Product Description

The PI3741-0x series is a high efficiency, wide range DC-DC ZVS Buck-Boost Regulator with two output range configurations that utilize the same high-density System-in-Package (SiP). Integrating controller, power switches, support components and a high-performance Zero-Voltage Switching (ZVS) topology within the PI3741-0x increases point-of-load performance while providing best-in-class power efficiency.

The PI3741-0x requires an external inductor, resistive divider and minimal capacitors to form a complete DC-DC switching mode buck-boost regulator.

Device	Output Voltage	
	Set	Range
PI3741-00-LGIZ	24V	21 – 36V
PI3741-01-LGIZ	48V	36 – 54V

The ZVS architecture also enables high-frequency operation while minimizing switching losses and maximizing efficiency. The high switching frequency operation reduces the size of the external filtering components, improves power density, and enables fast dynamic response to line and load transients.



Features & Benefits

- Up to 97% efficiency
- 150W of continuous output power (for specific conditions)
- Fast transient response
- Parallel capable with single-wire current sharing
- External frequency synchronization / interleaving
- High-Side Current Sense Amplifier
- General Purpose Amplifier
- Input Over/Undervoltage Lockout (OVLO/UVLO)
- Output Overvoltage Protection (OVP)
- Overtemperature Protection (OTP)
- Fast and slow current limits
- –40 to 115°C operating range (T_J)
- Excellent light-load efficiency

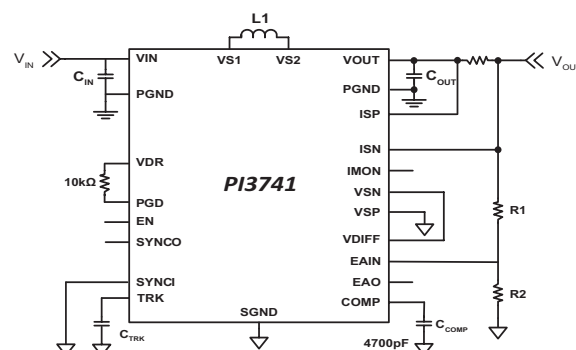
Applications

- Telecom, Networking, Lighting
- Computing, Communications, Industrial
- Renewable Energy Systems

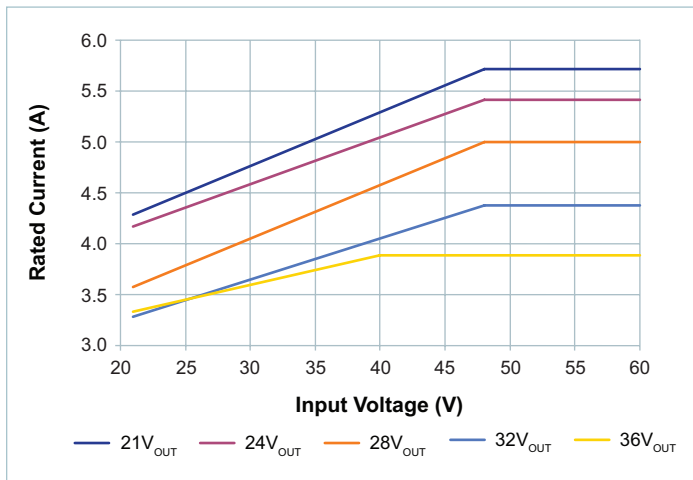
Package Information

- 10 x 14 x 2.56mm LGA SiP

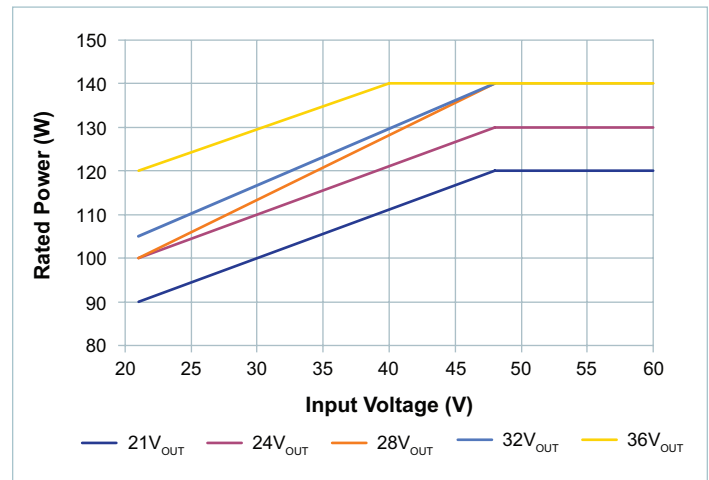
Typical Application



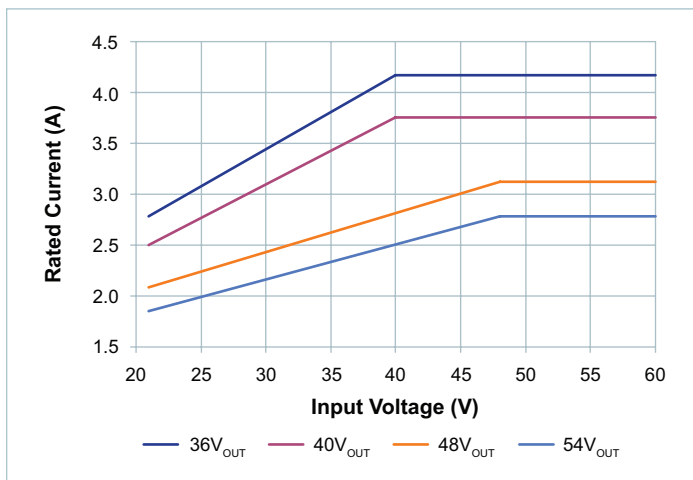
Rated Output Current / Power



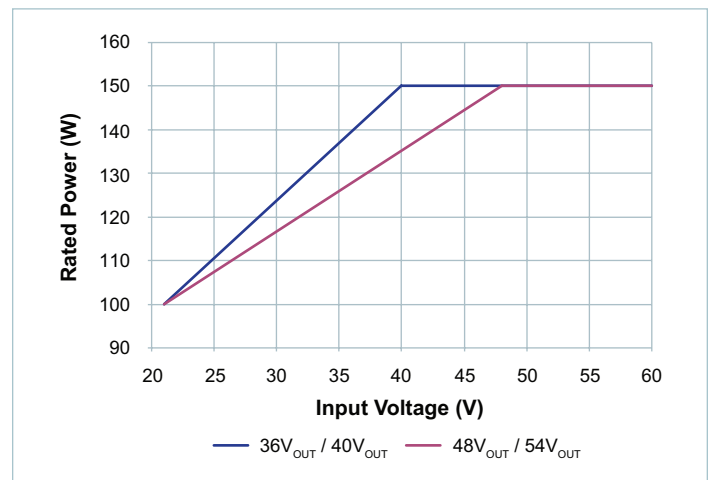
Output Current of PI3741-00-LGIZ



Output Power of PI3741-00-LGIZ



Output Current of PI3741-01-LGIZ



Output Power of PI3741-01-LGIZ

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Order Information

Part Number	Description	Package	Transport Media	MFG
PI3741-00-LGIZ	21 – 60V _{IN} to 21 – 36V _{OUT}	10mm x 14mm 108-pin LGA	TRAY	Vicor
PI3741-01-LGIZ	21 – 60V _{IN} to 36 – 54V _{OUT}	10mm x 14mm 108-pin LGA	TRAY	Vicor

Absolute Maximum Ratings

Note: Stresses beyond these limits may cause permanent damage to the device. Operation at these conditions or conditions beyond those listed in the Electrical Specifications table is not guaranteed. All voltage nodes are referenced to PGND unless otherwise noted.

Location	Name	V _{MAX}	V _{MIN}	I _{SOURCE}	I _{SINK}
1–2, G–K	V _{IN}	75V	–0.7V	40A ^[1]	40A ^[1]
4–5, G–K	VS1	75V	–0.7V _{DC}	40A ^[1]	18A ^[1]
10–11, G–K	VS2	75V	–0.7V _{DC}	40A ^[1]	18A ^[1]
13–14, G–K	V _{OUT}	75V	–0.7V _{DC}	40A ^[1]	40A ^[1]
1E	VDR	5.5V	–0.3V	30mA	200mA
1D	PGD	5.5V	–0.3V	20mA	20mA
1C	SYNCO	5.5V	–0.3V	5mA	5mA
1B	SYNCI	5.5V	–0.3V	5mA	5mA
1A	FT1	5.5V	–0.3V	5mA	5mA
2A	FT2	5.5V	–0.3V	5mA	5mA
3A	FT3	5.5V	–0.3V	5mA	5mA
4A	FT4	5.5V	–0.3V	10mA	10mA
5A	EN	5.5V	–0.3V	5mA	5mA
6A	TRK	5.5V	–0.3V	50mA	50mA
7A	LGH	5.5V	–0.3V	5mA	5mA
8A	COMP	5.5V	–0.3V	5mA	5mA
9A	VSN	5.5V	–1.5V	5mA	5mA
10A	VSP	5.5V	–1.5V	5mA	5mA
11A	VDIFF	5.5V	–0.5V	5mA	5mA
12A	EA _{IN}	5.5V	–0.3V	5mA	5mA
13A	EAO	5.5V	–0.3V	5mA	5mA
14A	IMON	5.5V	–0.3V	5mA	5mA
14D	ISN ^[2]	75V	–2V _{DC}	5mA	5mA
14E	ISP ^[2]	75V	–2V _{DC}	5mA	5mA
10–14, B + 10–12, C–E	SGND	0.3V	–0.3V	200mA	200mA
2–9, B–E + 7–8, F–K	PGND	N/A	N/A	18A ^[1]	18A ^[1]

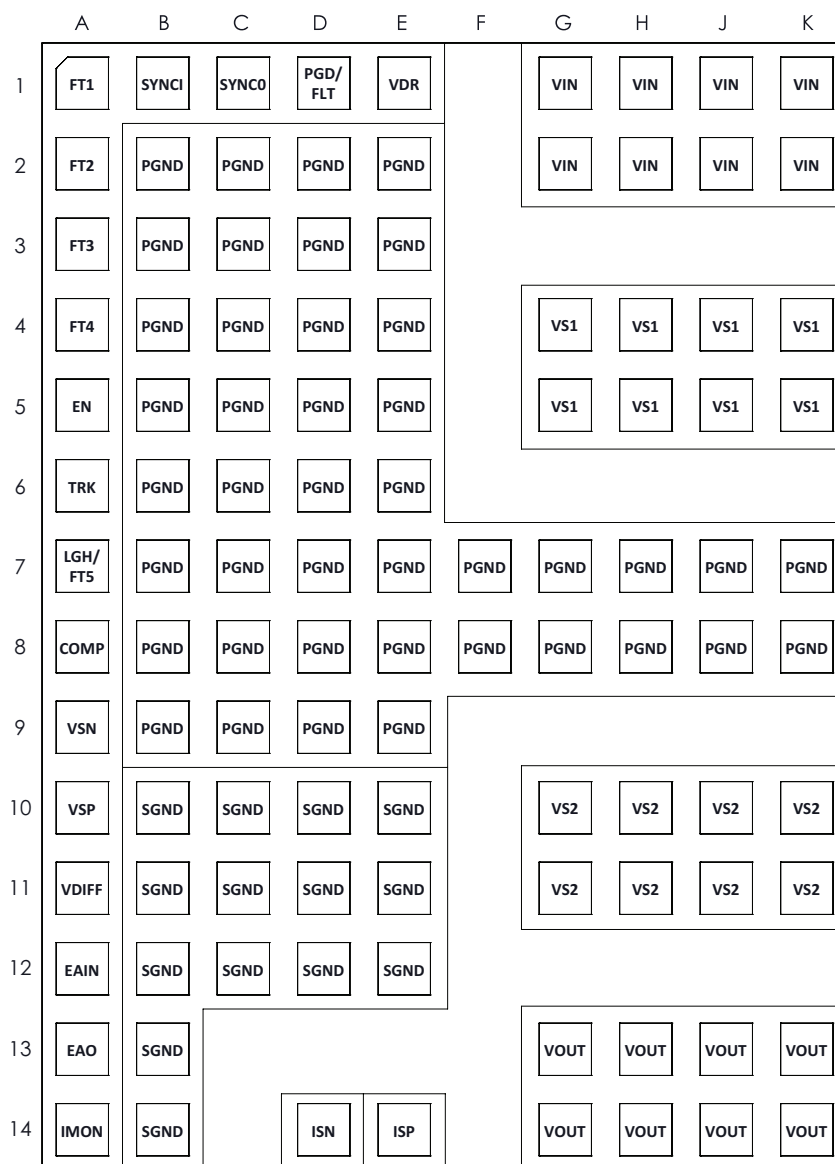
^[1] Non-Operating Test Mode Limits.

^[2] The ISP pin to ISN pin has a maximum differential limit of +5.5V_{DC} and -0.5V_{DC}.

Pin Description

Pin Number	Pin Name	Description
1–2, G–K	VIN	Input voltage and sense node for UVLO, OVLO and feed forward compensation.
4–5, G–K	VS1	Input side switching node and ZVS sense node for power switches.
10–11, G–K	VS2	Output side switching node and ZVS sense node for power switches.
13–14, G–K	VOUT	Output voltage and sense node for power switches, V_{OUT} feed forward compensation, V_{OUT_OV} and internal signals.
1E	VDR	Internal 5.1V supply for gate drivers and internal logic. May be used as reference or low power bias supply for up to 2mA. Must be impedance limited by the user.
1D	PGD	Fault & Power Good indicator. PGD pulls low when the regulator is not operating or if EAIN is less than 1.4V.
1C	SYNCO	Synchronization output. Outputs a high signal for $\frac{1}{2}$ of the programmed switching period at the beginning of each switching cycle, for synchronization of other regulators.
1B	SYNCI	Synchronization input. When a falling edge synchronization pulse is detected, the PI3741-0x will delay the start of the next switching cycle until the next falling edge sync pulse arrives, up to a maximum delay of two times the programmed switching period. If the next pulse does not arrive within two times the programmed switching period, the controller will leave sync mode and start a switching cycle automatically. Connect to SGND when not in use.
1A	FT1	For factory use only. Connect to SGND or leave floating in application.
2A	FT2	For factory use only. Connect to SGND or leave floating in application.
3A	FT3	For factory use only. Connect to SGND in application.
4A	FT4	For factory use only. Connect to SGND in application.
5A	EN	Regulator Enable control. Asserted high or left floating – regulator enabled; Asserted low, regulator output disabled.
6A	TRK	Soft-start and track input. An external capacitor may be connected between TRK pin and SGND to decrease the rate of output rise during soft-start.
7A	LGH	For factory use only. Connect to SGND in application.
8A	COMP	Error amp compensation dominant pole. Connect a capacitor of 4700pF by default between COMP and SGND to set the control loop dominant pole. If the application requires output capacitance from recommended in table 1, please contact Applications Support to compensate the control loop.
9A	VSN	General purpose amplifier inverting input.
10A	VSP	General purpose amplifier non-inverting input.
11A	VDIFF	General Purpose amplifier output. When unused connect VDIFF to VSN and VSP to SGND.
12A	EAIN	Error amplifier inverting input and sense for PGD. Connect by resistive divider to the output.
13A	EAO	Error amp output: External connection for additional compensation and current sharing. Leave floating to use the internal error amplifier capacitance for default loop compensation. Please contact Applications Support if additional compensation is needed.
14A	IMON	High side current sense amplifier output.
14D	ISN	High side current sense amplifier negative input.
14E	ISP	High side current sense amplifier positive input.
10–14, B + 10–12, C–E	SGND	Signal ground. Internal logic and analog ground for the regulator. SGND and PGND are star connected within the regulator package.
2–9, B–E + 7–8, F–K	PGND	Power ground. V_{IN} , V_{OUT} , VS1 and VS2 power returns. SGND and PGND are star connected within the regulator package.

Package Pin-Out



BB 10x14mm SiP

Large Pin Blocks

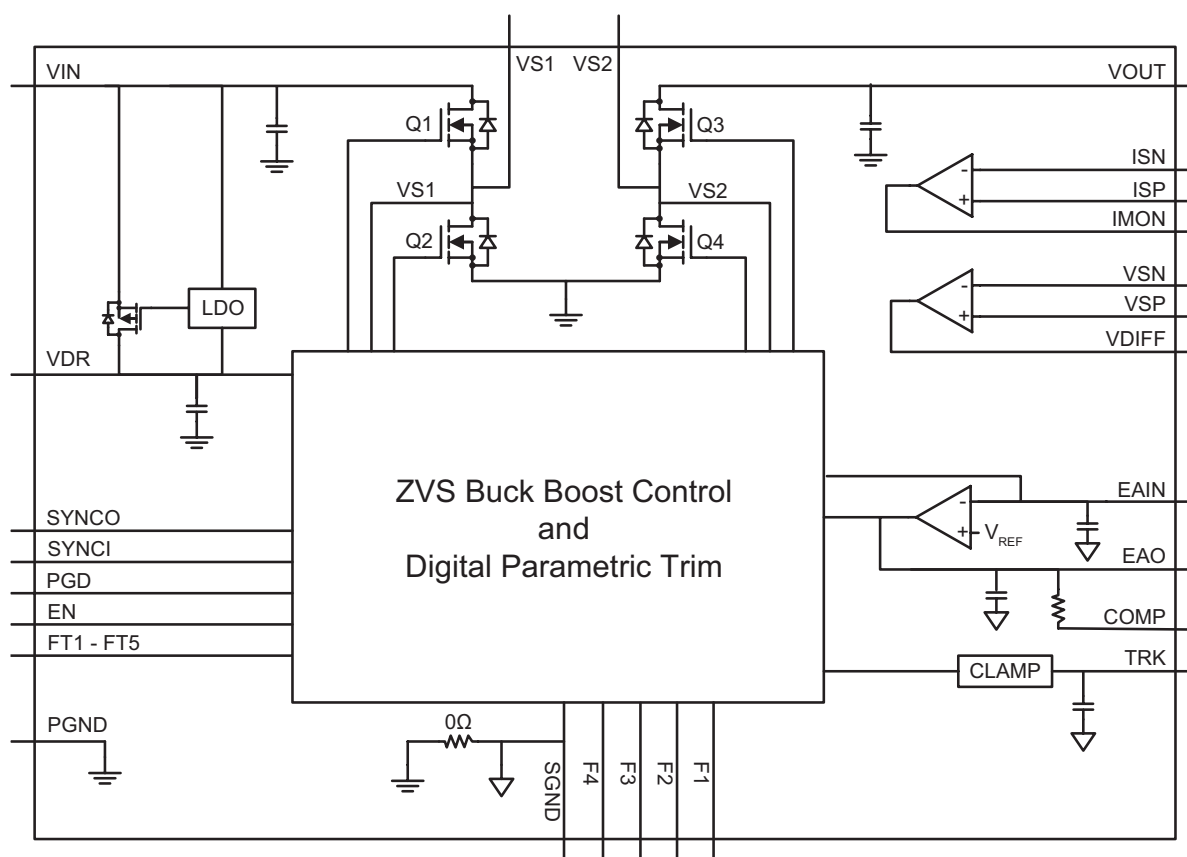
Pin Block Name	Group of pins
VIN	G1-2, H1-2, J1-2, K1-2
VS1	G4-5, H4-5, J4-5, K4-5
PGND	B2-9, C2-9, D2-9, E2-9, F7-8, G7-8, H7-8, J7-8, K7-8
VS2	G10-11, H10-11, J10-11, K10-11
VOUT	G13-14, H13-14, J13-14, K13-14
SGND	B10-14, C10-12, D10-12, E10-12

Storage and Handling Information

Maximum Storage Temperature Range	-65°C to 150°C
Maximum Operating Junction Temperature Range	-40°C to 115°C
Soldering Temperature for 20 seconds	245°C
MSL Rating	3
ESD Rating ^[3]	2.0kV HBM; 1.0kV CDM

^[3] JS-200-2014, JESD22-A114F.

Block Diagram



PI3741-00-LGIZ Electrical Characteristics

Specifications apply for the conditions $-40^{\circ}\text{C} < T_J < 115^{\circ}\text{C}$, $V_{\text{IN}} = 48\text{V}$, $V_{\text{OUT}} = 24\text{V}$, $L_{\text{EXT}} = 900\text{nH}$ ^[4], external $C_{\text{IN}} = 5 \times 2.2\mu\text{F}$, external $C_{\text{OUT}} = 8 \times 2.2\mu\text{F}$, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Input Specifications						
Input Voltage	$V_{\text{IN_DC}}$		21	48	60	V
Input Current During Output Short (Fault Condition Duty Cycle)	$I_{\text{IN_SHORT}}$	[5]		1.9		mA
Input Quiescent Current	$I_{\text{Q_VIN}}$	Enabled (no load)		4		mA
Input Quiescent Current	$I_{\text{Q_VIN}}$	Disabled		1.5		mA
Input Voltage Slew Rate	$V_{\text{IN_SR}}$	[5]			1	V / μs
Internal Input Capacitance	C_{IN}	25°C , $V_{\text{IN}} = 48\text{V}$		0.5		μF
V_{IN} UVLO Threshold Rising	$V_{\text{IN_UVLO_START}}$			19.2		V
V_{IN} UVLO Hysteresis	$V_{\text{IN_UVLO_HYS}}$			0.7		V
V_{IN} OVLO Threshold Rising	$V_{\text{IN_OVLO_START}}$		61	64.5	68	V
V_{IN} OVLO Hysteresis	$V_{\text{IN_OVLO_HYS}}$			1.3		V
Output Specifications						
EAIN Voltage Total Regulation	$V_{\text{EAIN_DC}}$		1.667	1.7	1.734	V
Output Voltage Range	$V_{\text{OUT_DC}}$		21	24	36	V
Output Current Range	$I_{\text{OUT_DCR}}$	[6]	0		max	A
Output Current Steady State	$I_{\text{OUT_DC}}$	$V_{\text{IN}} = 21 - 48\text{V}$, $V_{\text{OUT}} \leq 24\text{V}$, $T_{\text{CASE}} = 25^{\circ}\text{C}$ [6]	4.17			A
		$V_{\text{IN}} = 48 - 60\text{V}$, $V_{\text{OUT}} \leq 24\text{V}$, $T_{\text{CASE}} = 25^{\circ}\text{C}$ [6]	5.42			
Output Power Steady State	$P_{\text{OUT_DC}}$	$V_{\text{IN}} = 21 - 48\text{V}$, $V_{\text{OUT}} = 24 - 36\text{V}$, $T_{\text{CASE}} = 25^{\circ}\text{C}$ [6]	100			W
		$V_{\text{IN}} = 48 - 60\text{V}$, $V_{\text{OUT}} = 24 - 36\text{V}$, $T_{\text{CASE}} = 25^{\circ}\text{C}$ [6]	130			
Line Regulation	$\Delta V_{\text{OUT}}(\Delta V_{\text{IN}})$	@ 25°C , $21\text{V} < V_{\text{IN}} < 60\text{V}$		0.10		%
Load Regulation	$\Delta V_{\text{OUT}}(\Delta I_{\text{OUT}})$	@ 25°C , I_{OUT} above 5% of the typical full load		0.10		%
Output Ripple	$V_{\text{OUT_AC}}$	$I_{\text{OUT}} = 5.42\text{A}$, $V_{\text{IN}} = 48\text{V}$, $V_{\text{OUT}} = 24\text{V}$, $T_{\text{CASE}} = 25^{\circ}\text{C}$ $C_{\text{OUT_EX}} = 8 \times 2.2\mu\text{F}$, 100V, X7R, 20MHz BW		208		mVp-p
Internal Output Capacitance	C_{OUT}	25°C , $V_{\text{OUT}} = 24\text{V}$		0.75		μF
V_{OUT} Overvoltage Threshold	$V_{\text{OUT_OVT}}$	Rising V_{OUT} threshold to detect open loop	39.8	41.9	44	V
V_{OUT} Overvoltage Hysteresis	$V_{\text{OUT_OVH}}$			0.8		V
VDR						
V_{DR} Supply Voltage	V_{DR}	Generated internally	4.9	5.1	5.36	V
Current Sense Amplifier (Dedicated to monitor Input or Output Current)						
ISP Pin Bias Current (Sink)		$V_{\text{OUT}} = 10\text{V}$, Flows to SGND	90	150	260	μA
ISN Pin Bias Current		$V_{\text{OUT}} = 10\text{V}$		0		μA
Common Mode Input Range			8		60	V
IMON Source Current			1	1.8	3	mA
IMON Sink Current			1	1.6	2.6	mA
IMON Output At No Load			0	10	20	mV
Full Scale Error		40mV input	-4		4	%
Bandwidth		[5]		40		kHz
Settling Time For Full Scale Step		1%		20		μs
Gain	$A_{\text{V_CS}}$			20		V / V

PI3741-00-LGIZ Electrical Characteristics (Cont.)

Specifications apply for the conditions $-40^{\circ}\text{C} < T_J < 115^{\circ}\text{C}$, $V_{\text{IN}} = 48\text{V}$, $V_{\text{OUT}} = 24\text{V}$, $L_{\text{EXT}} = 900\text{nH}$ ^[4], external $C_{\text{IN}} = 5 \times 2.2\mu\text{F}$, external $C_{\text{OUT}} = 8 \times 2.2\mu\text{F}$, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
General Purpose Amplifier						
Open Loop Gain		[5]	96	120	140	dB
Small Signal Gain-Bandwidth		[5]	5	7	12	MHz
Offset			-1		1	mV
Common Mode Input Range			-0.1		2.5	V
Differential Mode Input Range					2	V
Maximum Output Voltage		IDIFF = -1mA			$V_{\text{DR}} - 0.2\text{V}$	V
Minimum Output Voltage		No Load			20	mV
Capacitive Load for Stable Operation		[5]	0		100	pF
Slew Rate				10		V / μs
Output Current			-1		1	mA
Transconductance Error Amplifier						
Reference	V_{REF}	EAIN = EAO, 25°C	1.688	1.7	1.712	V
		EAIN = EAO	1.674	1.7	1.726	
Input Range	V_{EAIN}	Note $V_{\text{EAIN_OV}}$ below	0		V_{DR}	V
Maximum Output Voltage			3.35	3.6	4.0	V
Minimum Output Voltage				0.05	0.15	V
Transconductance		Factory Set		7.6		mS
Zero Resistor		Factory Set		6		k Ω
EAO Output Current Sourcing		$V_{\text{EAO}} = 50\text{mV}$, $V_{\text{EAIN}} = 0\text{V}$		400		μA
EAO Output Current Sinking		$V_{\text{EAO}} = 2\text{V}$, $V_{\text{EAIN}} = 5\text{V}$		400		μA
Open Loop Gain		$R_{\text{OUT}} > 1\text{M}\Omega$ ^[5]	70	80		dB
Input Capacitance				56		pF
Output Capacitance				56		pF
Control and Protection						
Switching Frequency	F_{SW}			1		MHz
V_{EAO} Pulse Skip Threshold	$V_{\text{EAO_PST}}$	V_{EAO} to SGND		0.4		V
Control Node Range	V_{RAMP}		0		3.3	V
V_{EAO} Overload Threshold	$V_{\text{EAO_OL}}$	V_{EAO} to SGND	3.175	3.3	3.425	V
Overload Timeout	T_{OL}	$V_{\text{EAO}} > V_{\text{EAO_OL}}$		1		ms
Overload due to EAO limit	$I_{\text{OUT_EAO_LIM}}$	Module shuts down after 1ms of overload and restarts after 30ms		6.8		A
V_{EAIN} Output Overvoltage Threshold	$V_{\text{EAIN_OV}}$	$V_{\text{EAIN}} > V_{\text{EAIN_OV}}$	1.94	2.04	2.14	V
Overtemperature Fault Threshold	T_{OTP}	[5]		125		$^{\circ}\text{C}$
Overtemperature Restart Hysteresis	$T_{\text{OPT_HYS}}$	[5]		30		$^{\circ}\text{C}$
V_{OUT} Negative Fault Threshold			-0.45	-0.25	-0.15	V

PI3741-00-LGIZ Electrical Characteristics (Cont.)

Specifications apply for the conditions $-40^{\circ}\text{C} < T_J < 115^{\circ}\text{C}$, $V_{\text{IN}} = 48\text{V}$, $V_{\text{OUT}} = 24\text{V}$, $L_{\text{EXT}} = 900\text{nH}$ ^[4], external $C_{\text{IN}} = 5 \times 2.2\mu\text{F}$, external $C_{\text{OUT}} = 8 \times 2.2\mu\text{F}$, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Soft Start and Tracking Function						
TRK Active Range		Nominal	0		1.7	V
TRK Disable Threshold			20	45	70	mV
TRK Internal Capacitance				.047		μF
Soft Start Charge Current			30	50	70	μA
Soft Start Discharge Current		$V_{\text{TRK}} = 0.5\text{V}$		9		mA
Soft Start Time	t_{SS}	Ext $C_{\text{SS}} = 0\mu\text{F}$		1.6		ms
Enable						
Enable High Threshold	EN_{IH}		0.9	1	1.1	V
Enable Low Threshold	EN_{IL}		0.7	0.8	0.9	V
Enable Threshold Hysteresis	EN_{HYS}		100	200	300	mV
Enable Pin Bias Current		$V_{\text{EN}} = 0\text{V}$ or $V_{\text{EN}} = 2\text{V}$		± 50		μA
Enable Pull-up Voltage		Floating		2.0		V
Fault Restart Delay Time	$t_{\text{FR_DLY}}$			30		ms
Digital Signals						
SYNCl High Threshold		$V_{\text{DR}} = 5.1\text{V}$		1/2 VDR		V
SYNCO High	SYNCO_{OH}		$V_{\text{DR}} - 0.5$		V_{DR}	V
SYNCO Low	SYNCO_{OL}	$I_{\text{SYNCO}} = 1\text{mA}$			0.5	V
PGD High Leakage	PGD_{ILH}	$V_{\text{PGD}} = V_{\text{DR}}$			10	μA
PGD Output Low	PGD_{OL}	$I_{\text{PGD}} = 4\text{mA}$			0.4	V
PGD EAIN Low Rise			1.41	1.45	1.48	V
PGD EAIN Low Fall			1.36	1.41	1.46	V
PGD EAIN Threshold Hysteresis				35		mV
PGD EAIN High			1.94	2.04	2.14	V

^[4] See Inductor Pairing section.

^[5] Assured to meet performance specification by design, test correlation, characterization, and / or statistical process control.

^[6] Output current capability varies with input & output voltage. See rated output current / power curves on page 2.

PI3741-01-LGIZ Electrical Characteristics

Specifications apply for the conditions $-40^{\circ}\text{C} < T_J < 115^{\circ}\text{C}$, $V_{\text{IN}} = 48\text{V}$, $V_{\text{OUT}} = 48\text{V}$, $L_{\text{EXT}} = 900\text{nH}$ ^[4], external $C_{\text{IN}} = 5 \times 2.2\mu\text{F}$, external $C_{\text{OUT}} = 8 \times 2.2\mu\text{F}$, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Input Specifications						
Input Voltage	$V_{\text{IN_DC}}$		21	48	60	V
Input Current During Output Short (Fault Condition Duty Cycle)	$I_{\text{IN_SHORT}}$	[5]		1.9		mA
Input Quiescent Current	$I_{\text{Q_VIN}}$	Enabled (no load)		5		mA
Input Quiescent Current	$I_{\text{Q_VIN}}$	Disabled		1.5		mA
Input Voltage Slew Rate	$V_{\text{IN_SR}}$	[5]			1	V / μs
Internal Input Capacitance	C_{IN}	25°C , $V_{\text{IN}} = 48\text{V}$		0.5		μF
V_{IN} UVLO Threshold Rising	$V_{\text{IN_UVLO_START}}$			19.2		V
V_{IN} UVLO Hysteresis	$V_{\text{IN_UVLO_HYS}}$			0.7		V
V_{IN} OVLO Threshold Rising	$V_{\text{IN_OVLO_START}}$		61	64.5	68	V
V_{IN} OVLO Hysteresis	$V_{\text{IN_OVLO_HYS}}$			1.3		V
Output Specifications						
EAIN Voltage Total Regulation	$V_{\text{EAIN_DC}}$		1.667	1.7	1.734	V
Output Voltage Range	$V_{\text{OUT_DC}}$		36	48	54	V
Output Current Range	$I_{\text{OUT_DCR}}$	[6]	0		max	A
Output Current Steady State	$I_{\text{OUT_DC}}$	$V_{\text{IN}} = 21 - 48\text{V}$, $V_{\text{OUT}} \leq 48\text{V}$, $T_{\text{CASE}} = 25^{\circ}\text{C}$ [6]	2.09			A
		$V_{\text{IN}} = 48 - 60\text{V}$, $V_{\text{OUT}} \leq 48\text{V}$, $T_{\text{CASE}} = 25^{\circ}\text{C}$ [6]	3.13			
Output Power Steady State	$P_{\text{OUT_DC}}$	$V_{\text{IN}} = 21 - 48\text{V}$, $V_{\text{OUT}} = 48 - 54\text{V}$, $T_{\text{CASE}} = 25^{\circ}\text{C}$ [6]	100			W
		$V_{\text{IN}} = 48 - 60\text{V}$, $V_{\text{OUT}} = 48 - 54\text{V}$, $T_{\text{CASE}} = 25^{\circ}\text{C}$ [6]	150			
Line Regulation	$\Delta V_{\text{OUT}}(\Delta V_{\text{IN}})$	@ 25°C , $21\text{V} < V_{\text{IN}} < 60\text{V}$		0.10		%
Load Regulation	$\Delta V_{\text{OUT}}(\Delta I_{\text{OUT}})$	@ 25°C , I_{OUT} above 5% of the typical full load		0.10		%
Output Ripple	$V_{\text{OUT_AC}}$	$I_{\text{OUT}} = 3.13\text{A}$, $V_{\text{IN}} = 48\text{V}$, $V_{\text{OUT}} = 48\text{V}$, $T_{\text{CASE}} = 25^{\circ}\text{C}$ $C_{\text{OUT_EX}} = 8 \times 2.2\mu\text{F}$, 100V, X7R, 20MHz BW		320		mVp-p
Internal Output Capacitance	C_{OUT}	25°C , $V_{\text{OUT}} = 48\text{V}$		0.5		μF
V_{OUT} Overvoltage Threshold	$V_{\text{OUT_OVT}}$	Rising V_{OUT} threshold to detect open loop	60	63.1	66.3	V
V_{OUT} Overvoltage Hysteresis	$V_{\text{OUT_OVH}}$			1.3		V
VDR						
V_{DR} Supply Voltage	V_{DR}	Generated Internally	4.9	5.1	5.36	V
Current Sense Amplifier (Dedicated to monitor Input or Output Current)						
ISP Pin Bias Current (Sink)		$V_{\text{OUT}} = 10\text{V}$, Flows to SGND	90	150	260	μA
ISN Pin Bias Current		$V_{\text{OUT}} = 10\text{V}$		0		μA
Common Mode Input Range			8		60	V
IMON Source Current			1	1.8	3	mA
IMON Sink Current			1	1.6	2.6	mA
IMON Output At No Load			0		10	mV
Full Scale Error		40mV input	-4		4	%
Bandwidth		[5]		40		kHz
Settling Time For Full Scale Step		1%		20		μs
Gain	$A_{\text{V_CS}}$			20		V / V

PI3741-01-LGIZ Electrical Characteristics (Cont.)

Specifications apply for the conditions $-40^{\circ}\text{C} < T_J < 115^{\circ}\text{C}$, $V_{\text{IN}} = 48\text{V}$, $V_{\text{OUT}} = 48\text{V}$, $L_{\text{EXT}} = 900\text{nH}$ ^[4], external $C_{\text{IN}} = 5 \times 2.2\mu\text{F}$, external $C_{\text{OUT}} = 8 \times 2.2\mu\text{F}$, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
General Purpose Amplifier						
Open Loop Gain		[5]	96	120	140	dB
Small Signal Gain-Bandwidth		[5]	5	7	12	MHz
Offset			-1		1	mV
Common Mode Input Range			-0.1		2.5	V
Differential Mode Input Range					2	V
Maximum Output Voltage		IDIFF = -1mA			$V_{\text{DR}} - 0.2\text{V}$	V
Minimum Output Voltage		No Load			20	mV
Capacitive Load for Stable Operation		[5]	0		100	pF
Slew Rate				10		V / μs
Output Current			-1		1	mA
Transconductance Error Amplifier						
Reference	V_{REF}	EAIN = EAO, 25°C	1.688	1.7	1.712	V
		EAIN = EAO	1.674	1.7	1.726	
Input Range	V_{EAIN}	Note $V_{\text{EAIN_OV}}$ below	0		V_{DR}	V
Maximum Output Voltage			3.35	3.6	4.0	V
Minimum Output Voltage				0.05	0.15	V
Transconductance		Factory Set		5.1		mS
Zero Resistor		Factory Set		5		k Ω
EAO Output Current Sourcing		$V_{\text{EAO}} = 50\text{mV}$, $V_{\text{EAIN}} = 0\text{V}$		400		μA
EAO Output Current Sinking		$V_{\text{EAO}} = 2\text{V}$, $V_{\text{EAIN}} = 5\text{V}$		400		μA
Open Loop Gain		$R_{\text{OUT}} > 1\text{M}\Omega$ ^[5]	70	80		dB
Input Capacitance				56		pF
Output Capacitance				56		pF
Control and Protection						
Switching Frequency	F_{SW}			1		MHz
V_{EAO} Pulse Skip Threshold	$V_{\text{EAO_PST}}$	V_{EAO} to SGND		0.4		V
Control Node Range	V_{RAMP}		0		3.3	V
V_{EAO} Overload Threshold	$V_{\text{EAO_OL}}$	V_{EAO} to SGND	3.175	3.3	3.425	V
Overload Timeout	T_{OL}	$V_{\text{EAO}} > V_{\text{EAO_OL}}$		1		ms
Overload due to EAO limit	$I_{\text{OUT_EAOLIM}}$	Module shuts down after 1ms of overload and restarts after 30ms		5.0		A
V_{EAIN} Output Overvoltage Threshold	$V_{\text{EAIN_OV}}$	$V_{\text{EAIN}} > V_{\text{EAIN_OV}}$	1.94	2.04	2.14	V
Overtemperature Fault Threshold	T_{OTP}	[5]		125		$^{\circ}\text{C}$
Overtemperature Restart Hysteresis	$T_{\text{OPT_HYS}}$	[5]		30		$^{\circ}\text{C}$
V_{OUT} Negative Fault Threshold			-0.45	-0.25	-0.15	V

PI3741-01-LGIZ Electrical Characteristics (Cont.)

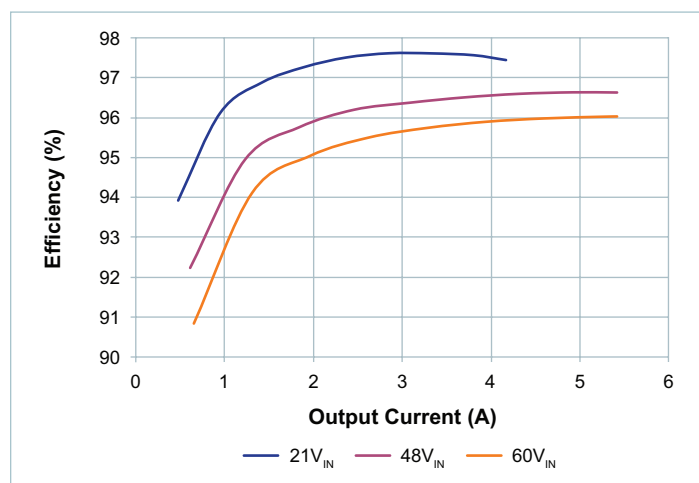
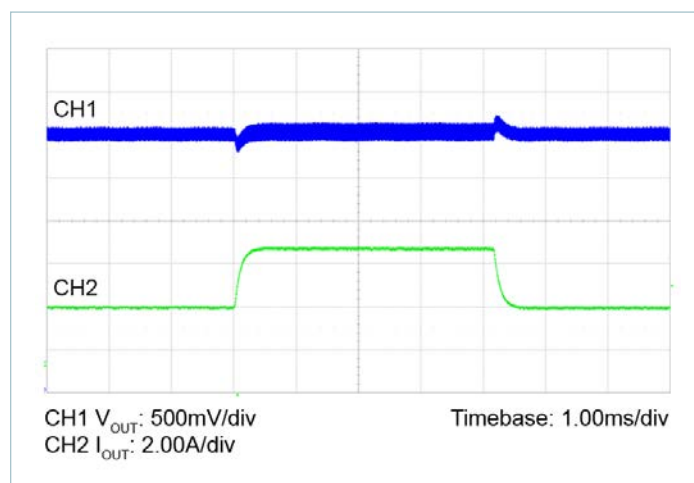
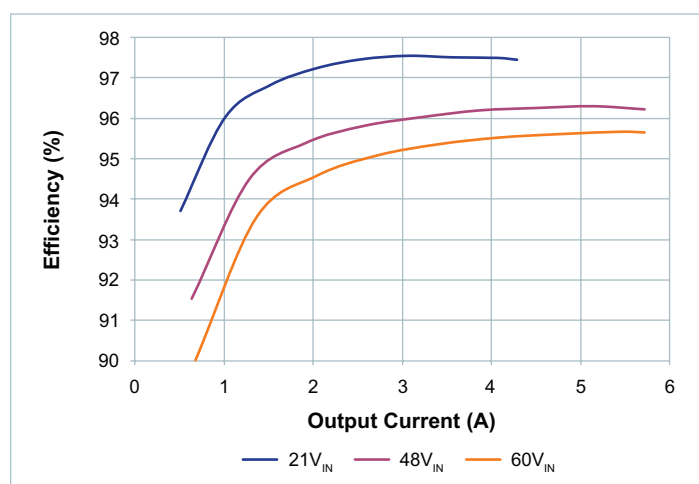
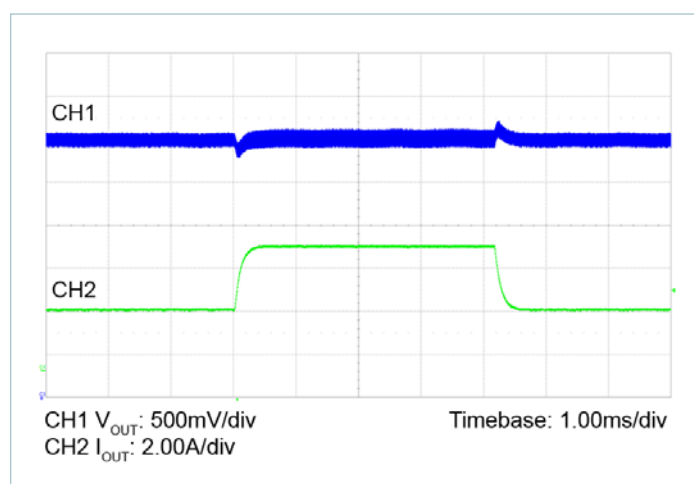
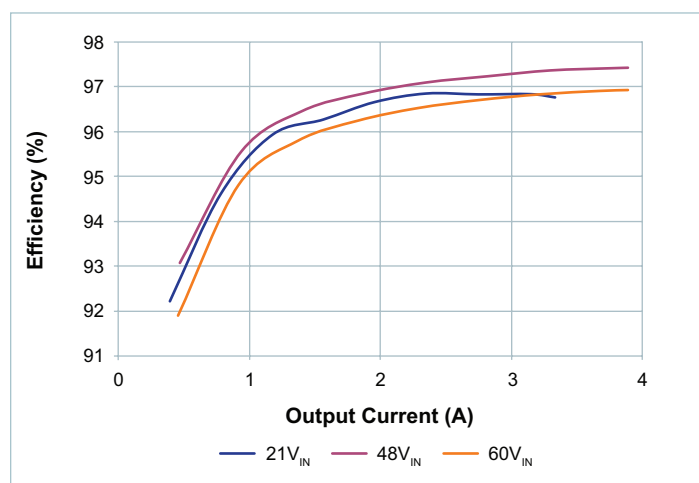
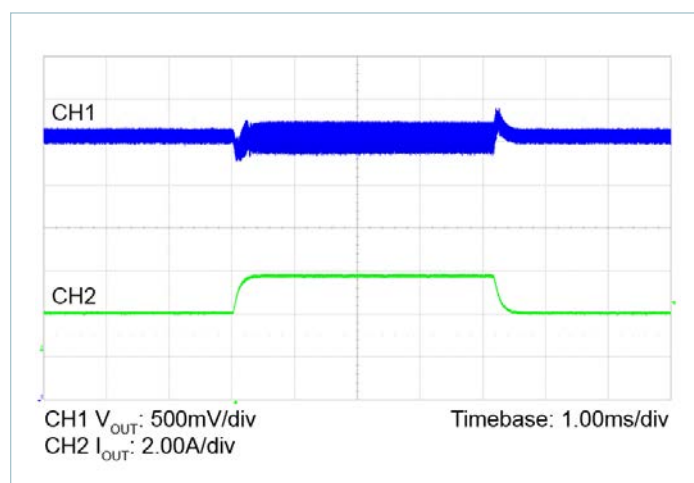
Specifications apply for the conditions $-40^{\circ}\text{C} < T_J < 115^{\circ}\text{C}$, $V_{\text{IN}} = 48\text{V}$, $V_{\text{OUT}} = 48\text{V}$, $L_{\text{EXT}} = 900\text{nH}$ ^[4], external $C_{\text{IN}} = 5 \times 2.2\mu\text{F}$, external $C_{\text{OUT}} = 8 \times 2.2\mu\text{F}$, unless otherwise noted.

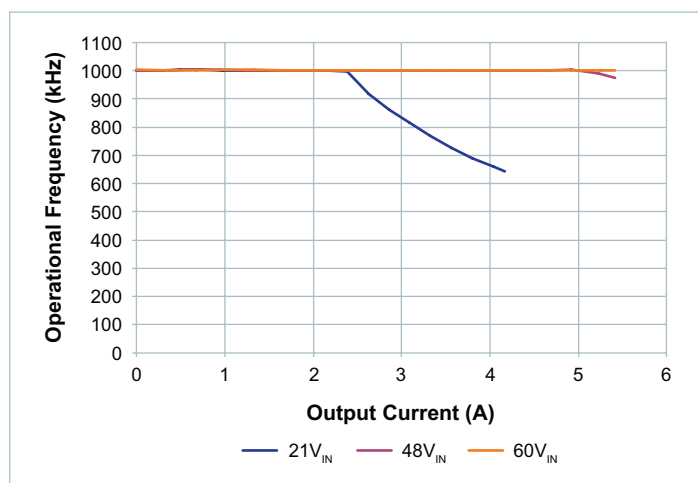
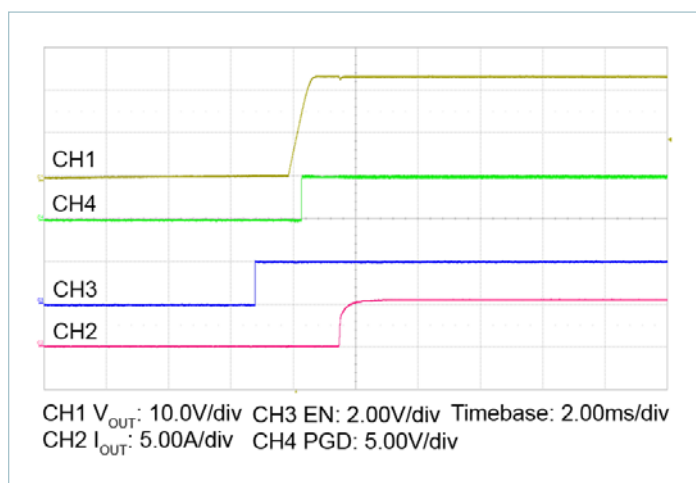
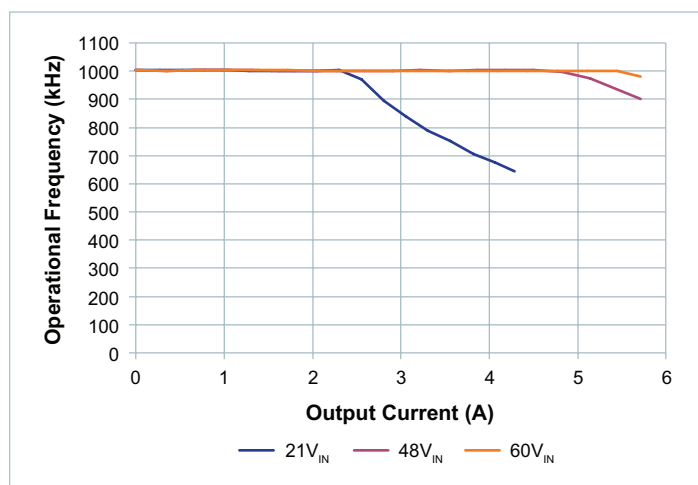
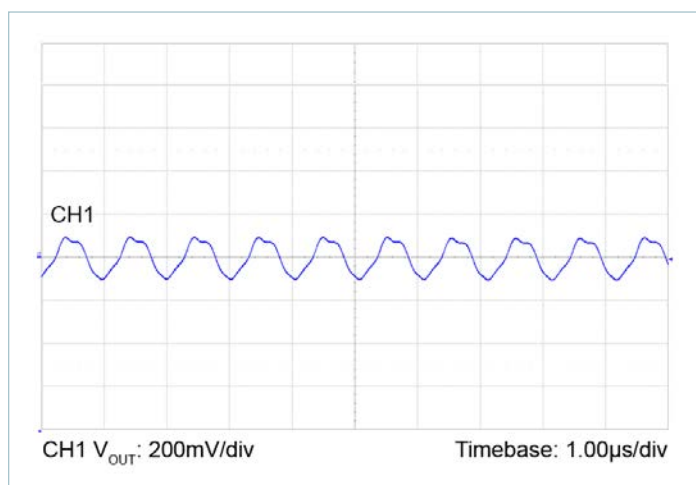
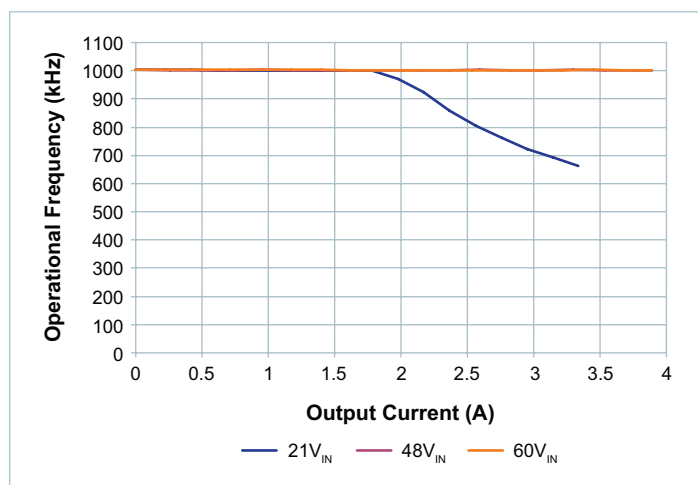
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Soft Start and Tracking Function						
TRK Active Range		Nominal	0		1.7	V
TRK Disable Threshold			20	45	70	mV
TRK Internal Capacitance				.047		μF
Soft Start Charge Current			30	50	70	μA
Soft Start Discharge Current		$V_{\text{TRK}} = 0.5\text{V}$		9		mA
Soft Start Time	t_{SS}	Ext $C_{\text{SS}} = 0\mu\text{F}$		1.6		ms
Enable						
Enable High Threshold	EN_{IH}		0.9	1	1.1	V
Enable Low Threshold	EN_{IL}		0.7	0.8	0.9	V
Enable Threshold Hysteresis	EN_{HYS}		100	200	300	mV
Enable Pin Bias Current		$V_{\text{EN}} = 0\text{V}$ or $V_{\text{EN}} = 2\text{V}$		± 50		μA
Enable Pull-up Voltage		Floating		2.0		V
Fault Restart Delay Time	$t_{\text{FR_DLY}}$			30		ms
Digital Signals						
SYNCl High Threshold		$V_{\text{DR}} = 5.1\text{V}$		1/2 VDR		V
SYNCO High	SYNCO_{OH}		$V_{\text{DR}} - 0.5$		V_{DR}	V
SYNCO Low	SYNCO_{OL}	$I_{\text{SYNCO}} = 1\text{mA}$			0.5	V
PGD High Leakage	PGD_{ILH}	$V_{\text{PGD}} = V_{\text{DR}}$			10	μA
PGD Output Low	PGD_{OL}	$I_{\text{PGD}} = 4\text{mA}$			0.4	V
PGD EAIN Low Rise			1.41	1.45	1.48	V
PGD EAIN Low Fall			1.36	1.41	1.46	V
PGD EAIN Threshold Hysteresis				35		mV
PGD EAIN High			1.94	2.04	2.14	V

^[4] See Inductor Pairing section.

^[5] Assured to meet performance specification by design, test correlation, characterization, and/or statistical process control.

^[6] Output current capability varies with input & output voltage. See rated output current / power curves on page 2.

PI3741-00-LGIZ Performance Characteristics $T_A = 25^\circ\text{C}$ Figure 1 — 24V_{OUT} EfficiencyFigure 4 — 48V_{IN} to 24V_{OUT}, $C_{OUT} = 8 \times 2.2\mu\text{F}$ Ceramic
5.42A to 2.71A Load Step, 0.1A/ μs Figure 2 — 21V_{OUT} EfficiencyFigure 5 — 60V_{IN} to 21V_{OUT}, $C_{OUT} = 8 \times 2.2\mu\text{F}$ Ceramic
5.72A to 2.86A Load Step, 0.1A/ μs Figure 3 — 36V_{OUT} EfficiencyFigure 6 — 21V_{IN} to 36V_{OUT}, $C_{OUT} = 8 \times 2.2\mu\text{F}$ Ceramic
3.34A to 1.67A Load Step, 0.1A/ μs

PI3741-00-LGIZ Performance Characteristics $T_A = 25^\circ\text{C}$ (Cont.)Figure 7 — Switching Frequency vs. Output Current @ 24V_{OUT}Figure 10 — Start-up with 48V_{IN} to 24V_{OUT} at 5.42A,
Ext C_{SS} = 0μFFigure 8 — Switching Frequency vs. Output Current @ 21V_{OUT}Figure 11 — Output voltage ripple at 48V_{IN} to 24V_{OUT}, 5.42A;
C_{OUT} = 8 x 2.2μF CeramicFigure 9 — Switching Frequency vs. Output Current @ 36V_{OUT}

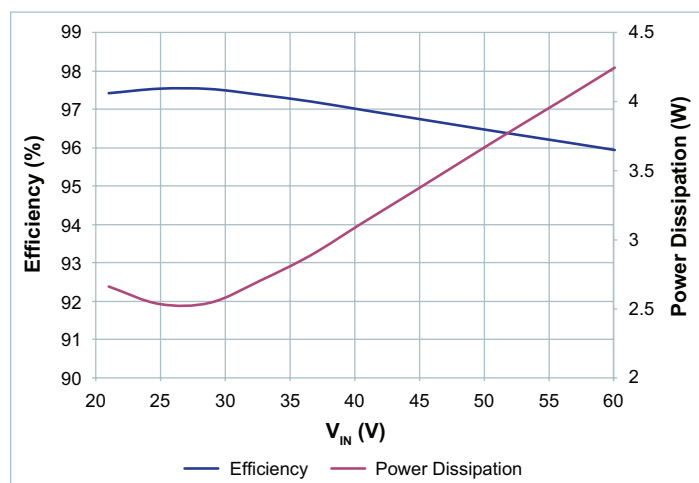
PI3741-00-LGIZ Efficiency & Power Loss $T_A = 25^\circ\text{C}$ ^[7] (Cont.)

Figure 12 — $24V_{OUT}$ Efficiency and Power Dissipation at maximum current (4.17A) over full input dynamic range

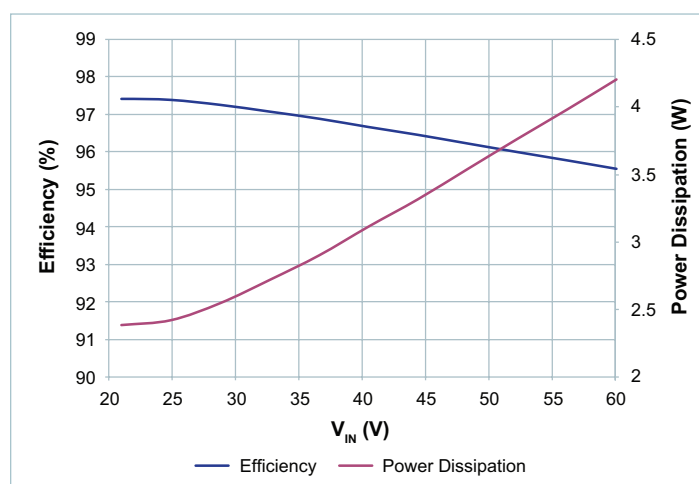


Figure 13 — $21V_{OUT}$ Efficiency and Power Dissipation at maximum current (4.29A) over full input dynamic range

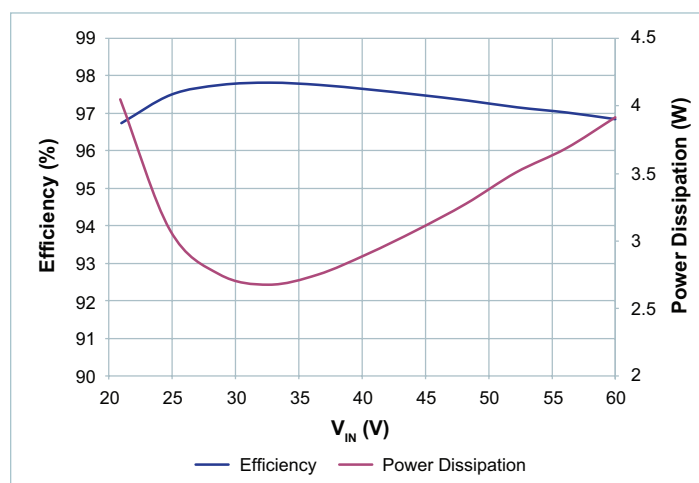
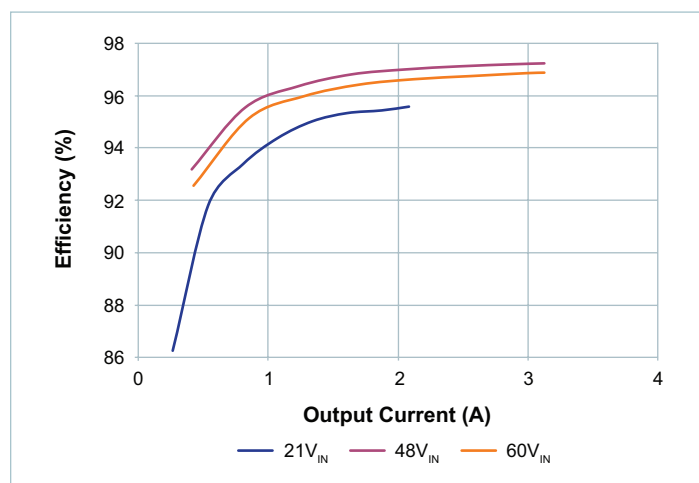
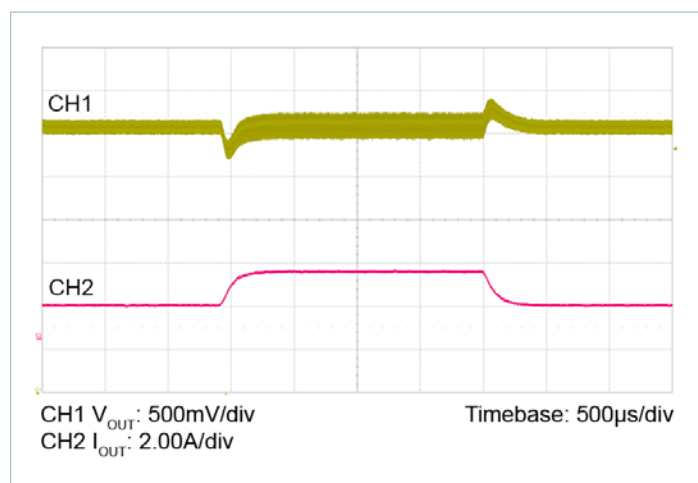
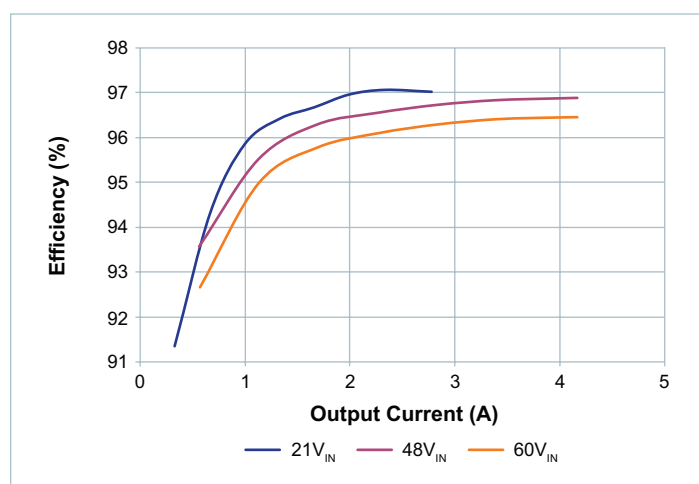
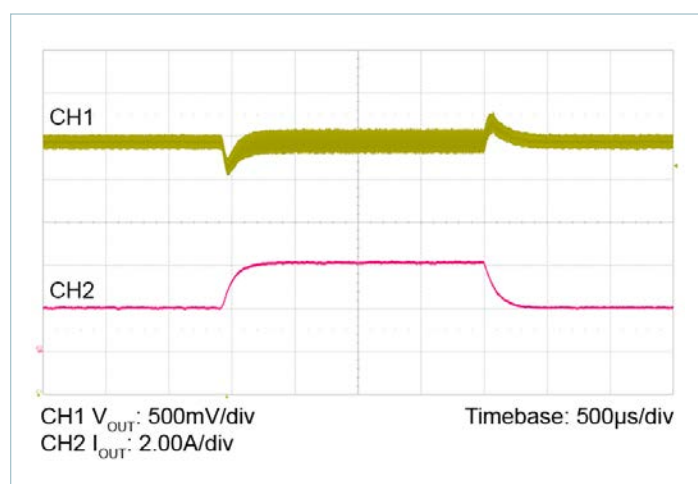
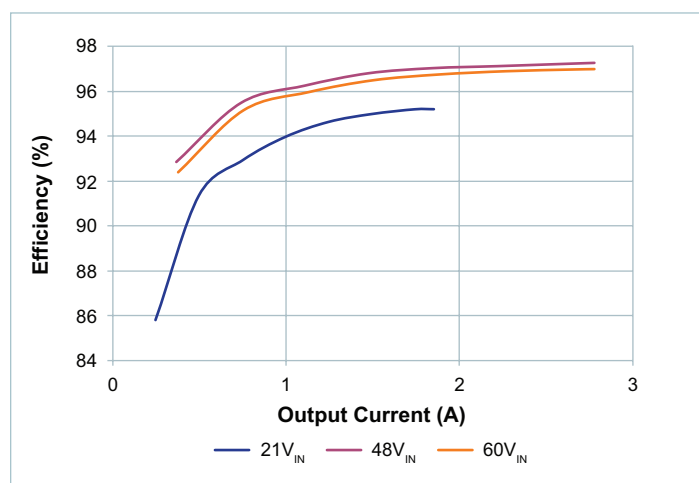
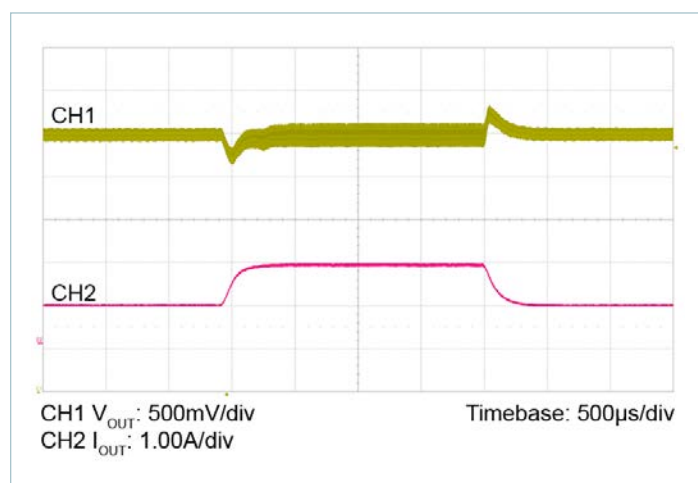
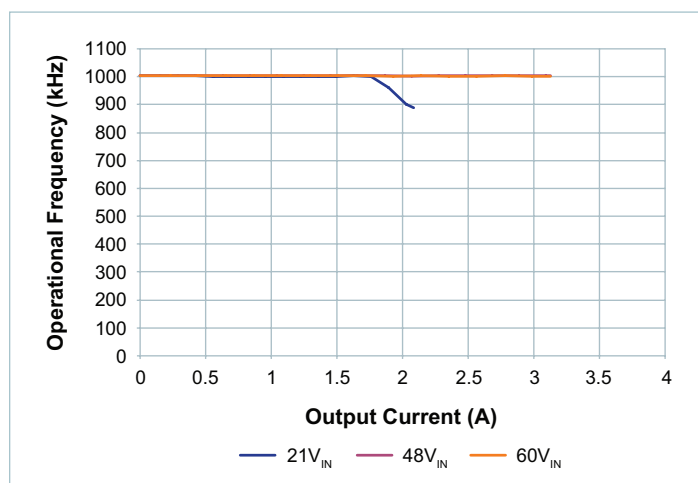
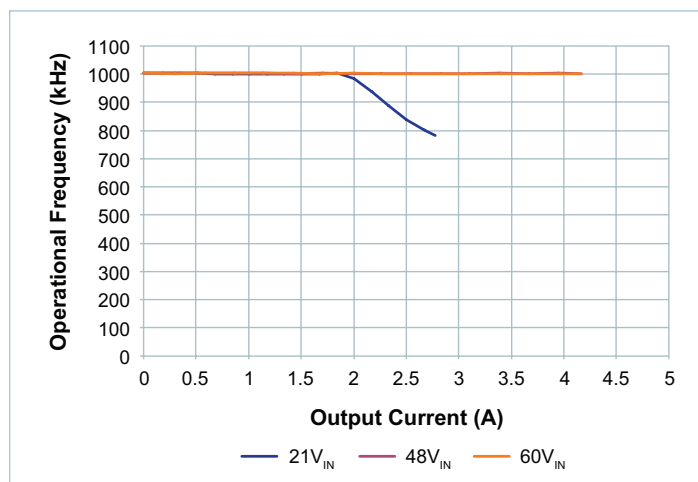
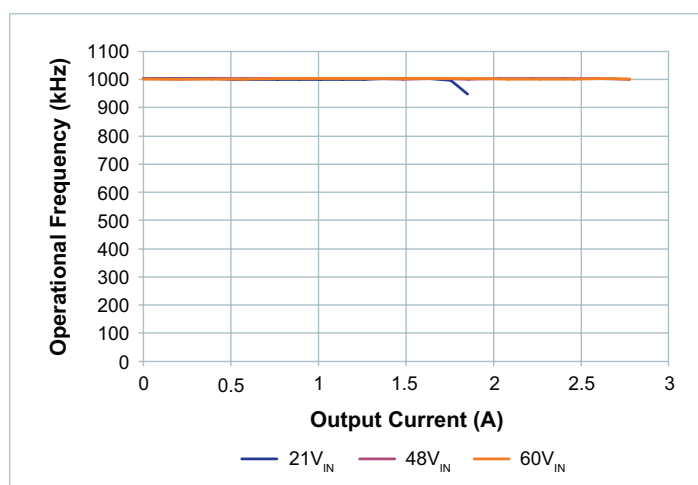
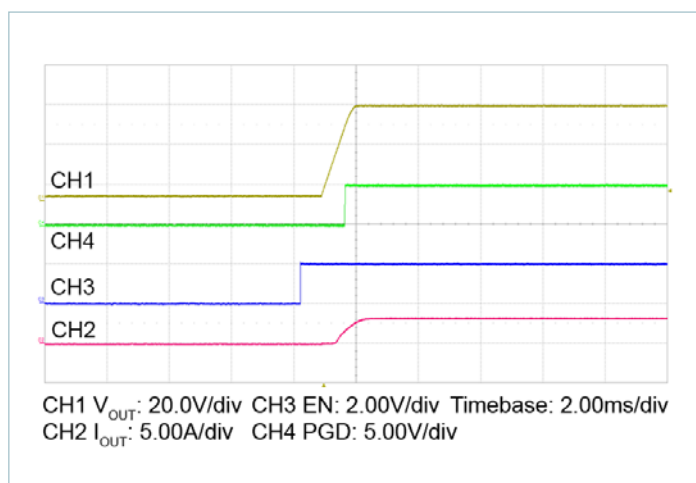
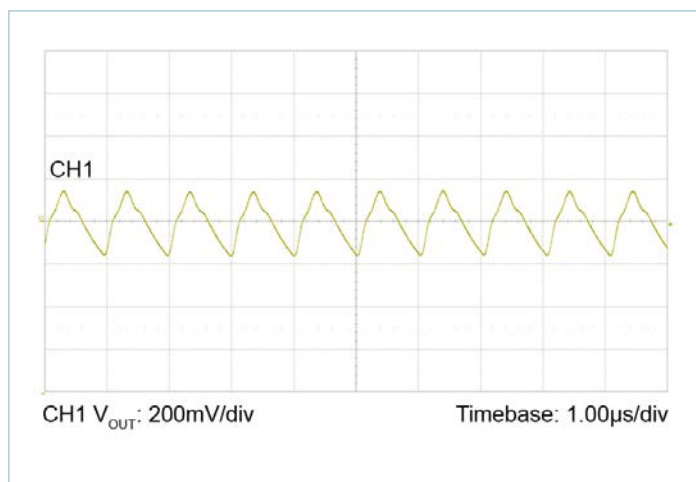


Figure 14 — $36V_{OUT}$ Efficiency and Power Dissipation at maximum current (3.34A) over full input dynamic range

^[7] Note: Testing was performed using a 3in. x 3in., four 2oz. copper layers, FR4 evaluation board platform.

PI3741-01-LGIZ Performance Characteristics $T_A = 25^\circ\text{C}$ Figure 15 — 48V_{OUT} EfficiencyFigure 18 — 48V_{IN} to 48V_{OUT}, C_{OUT} = 8 x 2.2μF Ceramic
3.13A to 1.57A Load Step, 0.1A/μsFigure 16 — 36V_{OUT} EfficiencyFigure 19 — 60V_{IN} to 36V_{OUT}, C_{OUT} = 8 x 2.2μF Ceramic
4.17A to 2.09A Load Step, 0.1A/μsFigure 17 — 54V_{OUT} EfficiencyFigure 20 — 21V_{IN} to 54V_{OUT}, C_{OUT} = 8 x 2.2μF Ceramic
1.86A to 0.93A Load Step, 0.1A/μs

PI3741-01-LGIZ Performance Characteristics $T_A = 25^\circ\text{C}$ (Cont.)Figure 21 — Switching Frequency vs. Output Current @ $48V_{OUT}$ Figure 22 — Switching Frequency vs. Output Current @ $36V_{OUT}$ Figure 23 — Switching Frequency vs. Output Current @ $54V_{OUT}$ Figure 24 — Start-up with $48V_{IN}$ to $48V_{OUT}$ at 3.13A, Ext $C_{SS} = 0\mu\text{F}$ Figure 25 — Output voltage ripple at $48V_{IN}$ to $48V_{OUT}$, 3.13A; $C_{OUT} = 8 \times 2.2\mu\text{F}$ Ceramic

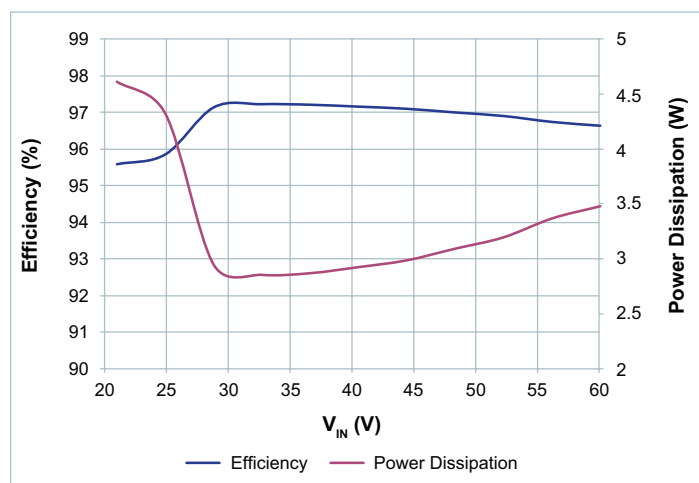
PI3741-01-LGIZ Efficiency & Power Loss $T_A = 25^\circ\text{C}$ ^[7] (Cont.)

Figure 26 — 48V_{OUT} Efficiency and Power Dissipation at maximum current (2.09A) over full input dynamic range

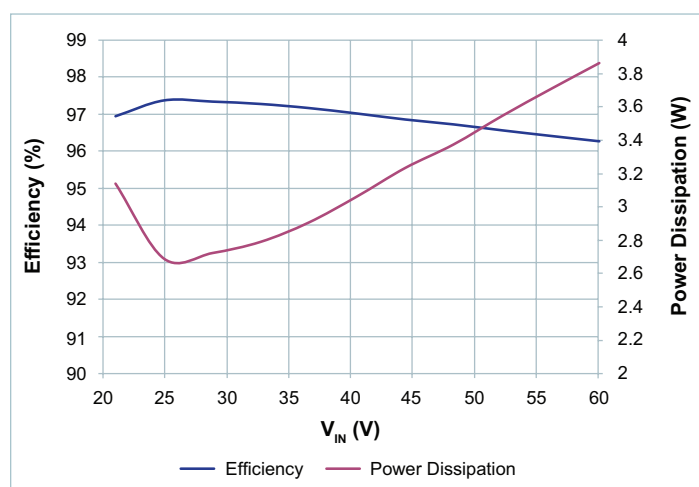


Figure 27 — 36V_{OUT} Efficiency and Power Dissipation at maximum current (2.78A) over full input dynamic range

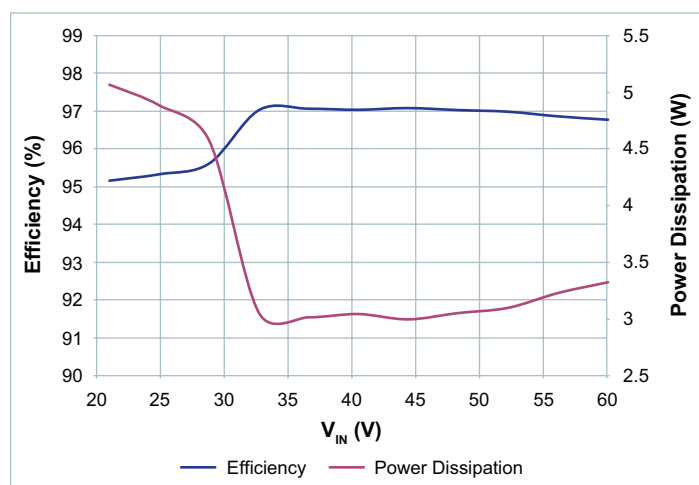


Figure 28 — 54V_{OUT} Efficiency and Power Dissipation at maximum current (1.86A) over full input dynamic range

^[7] Note: Testing was performed using a 3in. x 3in., four 2oz. copper layers, FR4 evaluation board platform.

MTBF

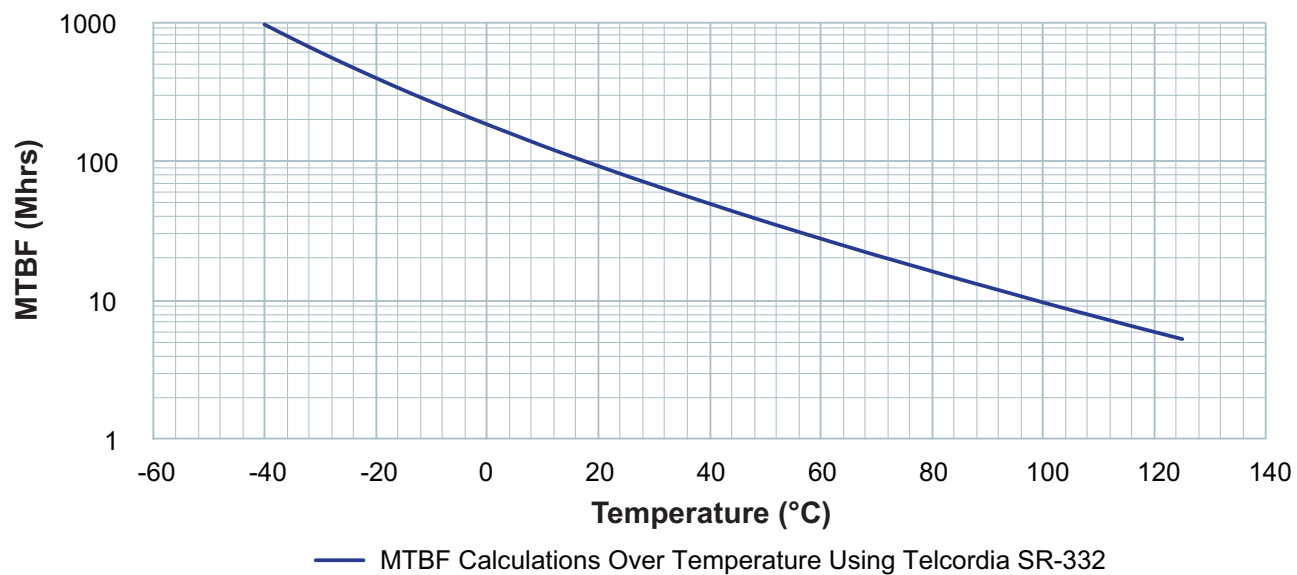


Figure 29 — PI3741-0x calculated MTBF Telcordia SR-332 GB

Output Overvoltage Protection

The PI3741-0x family is equipped with two methods of detecting an output over voltage condition. To prevent damage to input voltage sensitive devices, if the output voltage exceeds 20% of its set regulated value as measured by the EAIN pin (V_{EAIN_OV}), the regulator will complete the current cycle, stop switching and issue an OVP fault. Also if the output voltage of the regulator exceeds the V_{OUT} Overvoltage Threshold (V_{OUT_OVT}) then the regulator will complete the current cycle, stop switching and issue an OVP fault. The system will resume operation once the output voltage falls below the OVP threshold and after Fault Restart Delay.

Overtemperature Protection

The internal package temperature is monitored to prevent internal components from reaching their thermal maximum. If the Overtemperature Protection threshold is exceeded (T_{OTP}), the regulator will complete the current switching cycle, enter a low power mode, set a fault flag, and will soft-start when the internal temperature decreases by more than the Overtemperature Restart Hysteresis (T_{OTP_HYS}).

Pulse Skip Mode (PSM)

PI3741-0x features a hysteretic Pulse Skip Mode to achieve high efficiency at light loads. The regulator is setup to skip pulses if V_{EAO} falls below the Pulse Skip Threshold (V_{EAO_PST}). Depending on conditions and component values, this may result in single pulses or several consecutive pulses followed by skipped pulses. Skipping cycles significantly reduces gate drive power and improves light load efficiency. The regulator will leave Pulse Skip Mode once the control node rises above the Pulse Skip Mode threshold (V_{EAO_PST}).

Variable Frequency Operation

The PI3741-0x is preprogrammed to a fixed, maximum, base operating frequency. The frequency is selected with respect to the required power stage inductor to operate at peak efficiency across line and load variations. The switching frequency period will stretch as needed during each cycle to accommodate low line and or high load conditions. By stretching the switching frequency period, thus decreasing the switching frequency, the ZVS operation is preserved throughout the input line voltage range maintaining optimum efficiency.

IMON Amplifier

The PI3741-0x provides a differential amplifier with a level shifted, SGND referenced output, the IMON Pin, which is useful for sensing input or output current on high voltage rails. A fixed gain of 20:1 is provided over a large common mode range. When using the amplifier, the ISN pin must be referenced to the common mode voltage of the ISP pin for proper operation. See Absolute Maximum Ratings for more information. If not in use, the ISN and ISP pins should be connected to SGND and the IMON pin left floating.

Application Description

Output Voltage Trim

The output voltage can be adjusted by feeding back a portion of the desired output through a voltage divider to the error amplifier's input (see Figure 30). Equation 1 can be used to determine resistor values needed for the voltage divider.

$$R1 = R2 \cdot \left(\frac{V_{OUT}}{1.7} - 1 \right) \quad (1)$$

The R2 value is selected by the user; a 1.07kΩ resistor value is recommended.

If, for example, a 24V output is needed, the user can select a 1.07kΩ (1%) resistor for R2 and use Equation (1) to calculate R1. Once R1 value is calculated, the user should select the nearest resistor value available. In this example, R1 is 14.03kΩ so a 14.0kΩ should be selected.

Soft-Start Adjustment and Tracking

The TRK pin offers a means to increase the regulator's soft-start time or to track with additional regulators. The soft-start slope is controlled by an internal 47nF and a fixed charge current to provide a minimum startup time of 1.6ms (typical). By adding an external capacitor to the TRK pin, the soft-start time can be increased further. The following equation can be used to calculate the proper capacitor for a desired soft-start times:

$$C_{TRK} = \frac{(t_{TRK} \cdot I_{SS})}{1.7} - 47 \cdot 10^{-9} \quad (2)$$

Where, t_{TRK} is the desired soft-start time and I_{SS} is the TRK pin source current (see Electrical Characteristics for limits).

The PI3741-0x allows the tracking of multiple like regulators. Two methods of tracking can be chosen: proportional or direct tracking. Proportional tracking will force all connected regulators to startup and reach regulation at the same time (see Figure 31 (a)). To implement proportional tracking, simply connect all devices TRK pins together.

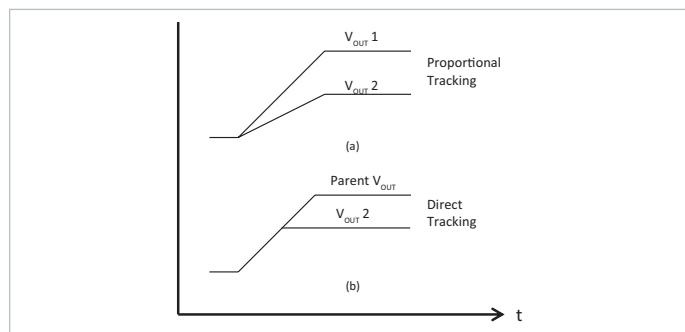


Figure 31 — PI3741-0x tracking methods

For Direct Tracking, choose the regulator with the highest output voltage as the parent and connect the parent to the TRK pin of the other regulators through a divider (Figure 32) with the same ratio as the child's feedback divider (see Output Voltage Trim). The TRK pin should not be driven without 1k minimum series resistance.

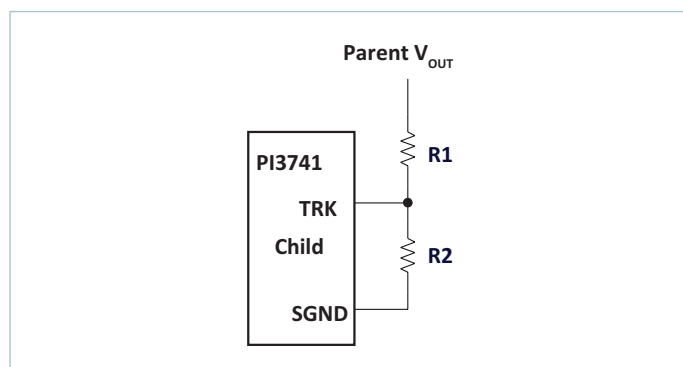


Figure 32 — Voltage divider connections for direct tracking

All connected regulators' soft-start slopes will track with this method. Direct tracking timing is demonstrated in Figure 31 (b). All tracking regulators should have their Enable (EN) pins connected together for proper operation.

Inductor Pairing

Operations and characterization of the PI3741-0x was performed using a 900nH inductor, Part # HCV1206-R90-R, manufactured by Eaton. This Inductor has a form factor of 12.5mm x 10mm x 5mm. No other inductor is recommended for use with the PI3741-0x. For additional inductor information and sourcing, please contact Eaton directly.

Filter Considerations

The PI3741-0x requires low impedance ceramic input capacitors (X7R/X5R or equivalent) to ensure proper start up and high frequency decoupling for the power stage. The PI3741-0x will draw nearly all of the high frequency current from the low impedance ceramic capacitors when the main high side MOSFET(s) are conducting. During the time the MOSFET(s) are off, the input capacitors are replenished from the source. Table 1 shows the recommended input and output capacitors to be used for the PI3741-0x. Divide the total RMS current by the number of ceramic capacitors used to calculate the individual capacitor's RMS current. Table 2 includes the recommended input and output ceramic capacitor. It is very important to verify that the voltage supply source as well as the interconnecting line are stable and do not oscillate.

Input Filter case 1; Inductive source and local, external, input decoupling capacitance with negligible ESR (i.e.: ceramic type)

The voltage source impedance can be modeled as a series R_{line} L_{line} circuit. The high performance ceramic decoupling capacitors will not significantly damp the network because of their low ESR; therefore in order to guarantee stability the following conditions must be verified:

$$R_{line} > \frac{L_{line}}{(C_{IN_INT} + C_{IN_EXT}) \cdot |r_{EQ_IN}|} \quad (3)$$

$$R_{line} << |r_{EQ_IN}| \quad (4)$$

Where r_{EQ_IN} can be calculated by dividing the lowest line voltage by the full load input current. It is critical that the line source impedance be at least an octave lower than the converter's dynamic input resistance, Equation (4). However, R_{line} cannot be made arbitrarily low otherwise Equation (3) is violated and the system will show instability, due to under-damped RLC input network.

C_{INPUT} (see Table 2)	C_{OUTPUT} (see Table 2)
5 X 2.2 μ F	8 X 2.2 μ F

Table 1 — Recommended input and output capacitance

Part Number	Description	MFG Description
GRM32ER72A225KA35	2.2 μ F Capacitor, X7R 20% 100V, 1210	Murata

Table 2 — Capacitor manufacturer part numbers

Input Filter case 2; Inductive source and local, external input decoupling capacitance with significant $R_{C_{IN_EXT}}$ ESR (i.e.: electrolytic type)

In order to simplify the analysis in this case, the voltage source impedance can be modeled as a simple inductor L_{line} . Notice that the high performance ceramic capacitors C_{IN_INT} within the PI3741-0x should be included in the external electrolytic capacitance value for this purpose. The stability criteria will be:

$$|r_{EQ_IN}| > R_{C_{IN_EXT}} \quad (5)$$

$$\frac{L_{line}}{C_{IN_INT} \cdot R_{C_{IN_EXT}}} < |r_{EQ_IN}| \quad (6)$$

Equation (6) shows that if the aggregate ESR is too small – for example by using very high quality input capacitors (C_{IN_EXT}) – the system will be under-damped and may even become destabilized. Again, an octave of design margin in satisfying Equation (5) should be considered the minimum.

Note: When applying an electrolytic capacitor for input filter damping the ESR value must be chosen to avoid loss of converter efficiency and excessive power dissipation in the electrolytic capacitor.

Part Number	V _{OUT} (V)	V _{IN} (V)	I _{OUT} (A)	C _{INPUT} Ripple Current (I _{RMS})	C _{OUTPUT} Ripple Current (I _{RMS})	Output Ripple (mVpp)	Input Ripple (mVpp)
PI3741-00-LGIZ	21	21	4.29	3.80	3.60	212	298
	21	48	5.72	3.91	4.41	202	562
	21	60	5.72	3.67	4.65	184	558
	24	21	4.17	4.31	4.19	238	315
	24	48	5.42	3.86	4.26	190	512
	24	60	5.42	3.68	4.55	193	583
	28	21	3.58	3.83	3.95	279	340
	28	48	5.00	3.76	4.06	210	501
	28	60	5.00	3.60	4.39	240	621
	32	21	3.29	4.36	4.39	308	378
	32	48	4.38	3.56	3.87	255	509
	32	60	4.38	3.50	4.28	264	590
	36	21	3.34	5.22	4.82	345	423
	36	48	3.89	3.46	3.76	280	507
	36	60	3.89	3.43	4.15	279	588
PI3741-01-LGIZ	36	21	2.78	3.76	3.86	197	263
	36	48	4.17	4.46	4.90	293	532
	36	60	4.17	4.32	5.24	294	602
	40	21	2.5	4.05	3.98	215	344
	40	48	3.75	4.35	4.76	308	534
	40	60	3.75	4.25	5.10	302	591
	48	21	2.09	4.28	3.94	294	334
	48	48	3.13	4.18	4.43	319	520
	48	60	3.13	4.12	4.75	320	576
	54	21	1.86	4.50	3.92	289	331
	54	48	2.78	4.03	4.15	340	528
	54	60	2.78	4.00	4.50	336	578

Table 3 — Typical input and output ripple current/voltage with the recommended input and output capacitor recommended in Tables 1 and 2.

Thermal Design

Figure 33 (a) shows a thermal impedance model that can predict the maximum temperature of the highest temperature component for a given operating condition. This model assumes that all customer PCB connections are at one temperature, which is PCB equivalent Temperature T_{PCB} °C. The model can be simplified as shown in Figure 33 (b).

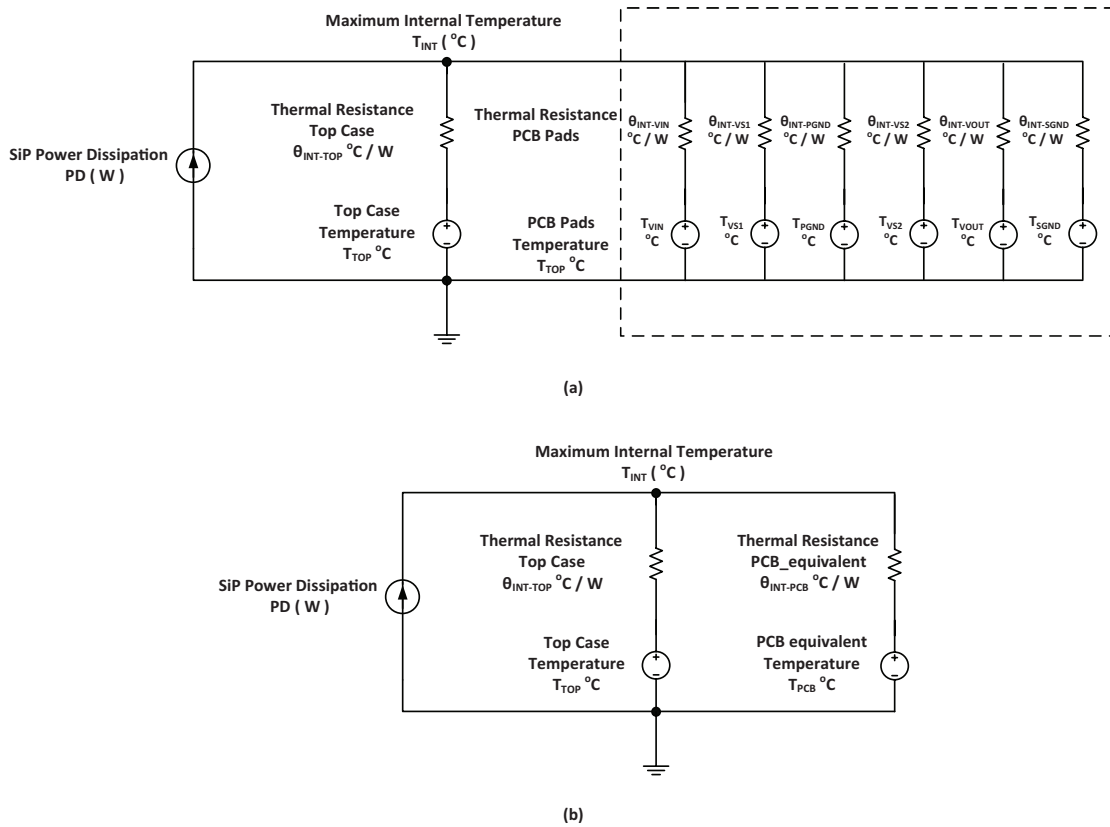


Figure 33 — PI3741-0x SiP Thermal Model (a) and its simplified version (b).

Where the symbol in Figure 33 is defined as the following:

$\theta_{INT-TOP}$	is defined as the thermal impedance from the hottest component junction inside the SiP to the top side of the package.
$\theta_{INT-PCB}$	is defined as the thermal impedance from the hottest component junction inside the SiP to the circuit board it is mounted on, assuming all customer PCB connections at one temperature.
$\theta_{INT-VIN}$	is defined as the thermal impedance from the hottest component junction inside the SiP to the circuit board it is mounted on at the V_{IN} pad.
$\theta_{INT-VS1}$	is defined as the thermal impedance from the hottest component junction inside the SiP to the circuit board it is mounted on at the VS1 pad.
$\theta_{INT-PGND}$	is defined as the thermal impedance from the hottest component junction inside the SiP to the circuit board it is mounted on at the PGND pad.
$\theta_{INT-VS2}$	is defined as the thermal impedance from the hottest component junction inside the SiP to the circuit board it is mounted on at the VS2 pad.
$\theta_{INT-VOUT}$	is defined as the thermal impedance from the hottest component junction inside the SiP to the circuit board it is mounted on at the V_{OUT} pad.
$\theta_{INT-SGND}$	is defined as the thermal impedance from the hottest component junction inside the SiP to the circuit board it is mounted on at the SGND pad.

The following equation can predict the junction temperature based on the heat load applied to the SiP and the known ambient conditions with the simplified thermal circuit model:

$$T_{INT} = \frac{PD + \frac{T_{TOP}}{\theta_{INT-TOP}} + \frac{T_{PCB}}{\theta_{INT-PCB}}}{\frac{1}{\theta_{INT-TOP}} + \frac{1}{\theta_{INT-PCB}}} \quad (7)$$

Device	Thermal Impedance							Thermal Impedance with the simplified version	
	$\theta_{INT-TOP}$ (°C / W)	$\theta_{INT-VIN}$ (°C / W)	$\theta_{INT-VS1}$ (°C / W)	$\theta_{INT-PGND}$ (°C / W)	$\theta_{INT-VS2}$ (°C / W)	$\theta_{INT-VOUT}$ (°C / W)	$\theta_{INT-SGND}$ (°C / W)	$\theta_{INT-TOP}$ (°C / W)	$\theta_{INT-PCB}$ (°C / W)
PI3741-00-LGIZ	62	5.0	12	24	27	6.6	180	62	1.9
PI3741-01-LGIZ	66	5.1	20	25	11	8.8	190	66	2.0

Table 4 — PI3741-0x SiP Thermal Impedance

Figure 34 (a) shows a thermal impedance model that can predict the maximum hot spot temperature of the inductor for a given operating condition. This model assumes that all customer PCB connections are at one temperature, which is PCB equivalent Temperature T_{PCB} °C. If the inductor top and bottom are not mounted to a heat sink, the simplified model is parallel combination of all resistances that connect to the PCB. The model can be simplified as shown in Figure 34 (b).

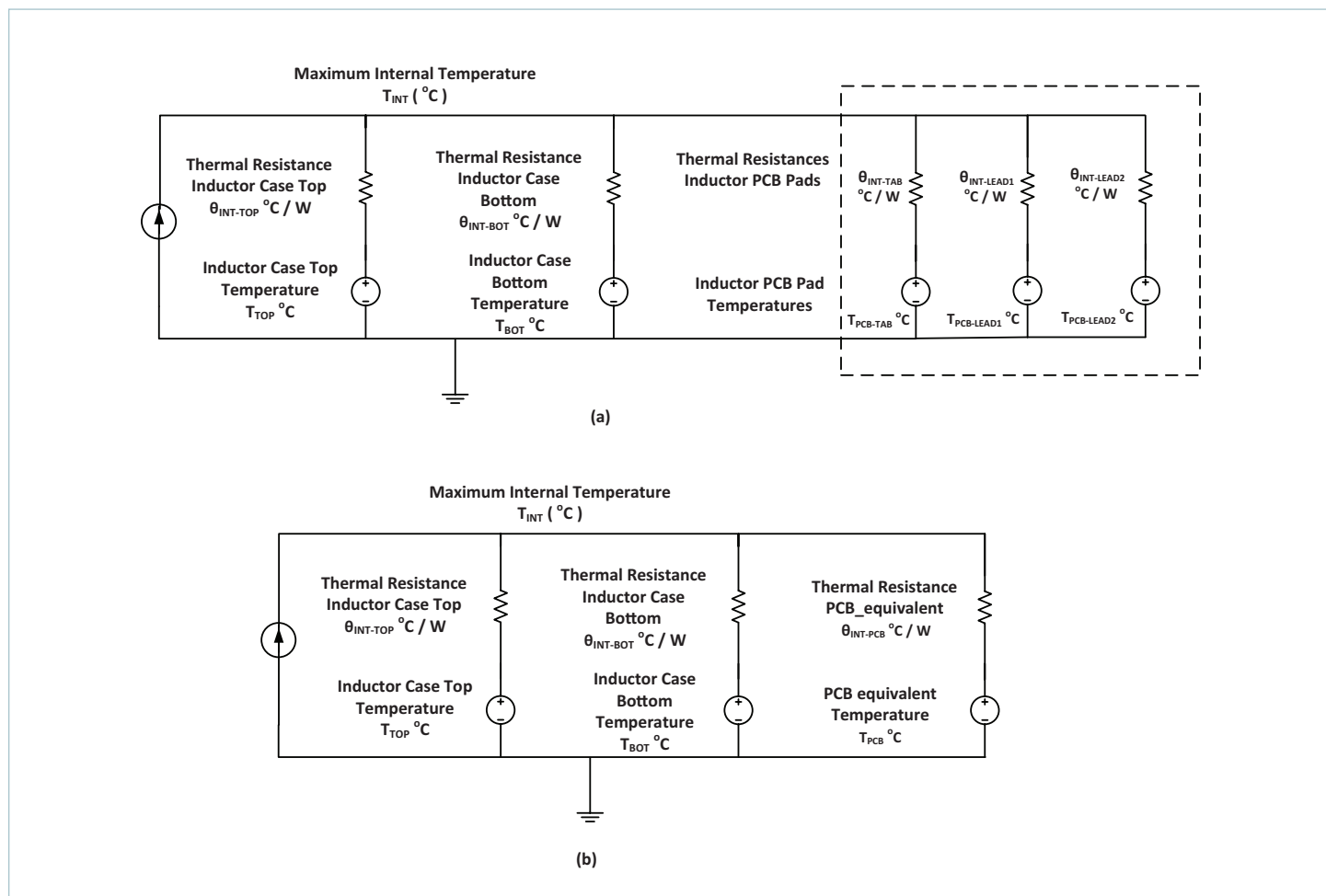


Figure 34 — PI3741-0x Inductor Thermal Impedance Model

Where the symbol in Figure 34 is defined as the following:

$\theta_{INT-TOP}$	is defined as the thermal impedance from the hot spot to the top surface of the core.
$\theta_{INT-PCB}$	is defined as the thermal impedance from the hot spot to the circuit board it is mounted on, assuming all customer PCB connections are at one temperature.
$\theta_{INT-BOT}$	is defined as the thermal impedance from the hot spot to the bottom surface of the core.
$\theta_{INT-TAB}$	is defined as the thermal impedance from the hot spot to the metal mounting tab on the core body.
$\theta_{INT-LEAD1}$	is defined as the thermal impedance from the hot spot to one of the mounting leads. Since the leads are the same thermal impedance, there is no need to specify by explicit pin number
$\theta_{INT-LEAD2}$	is defined as the thermal impedance from the hot spot to the other mounting lead

The following equation can predict the junction temperature based on the heat load applied to the inductor and the known ambient conditions with the simplified thermal circuit model:

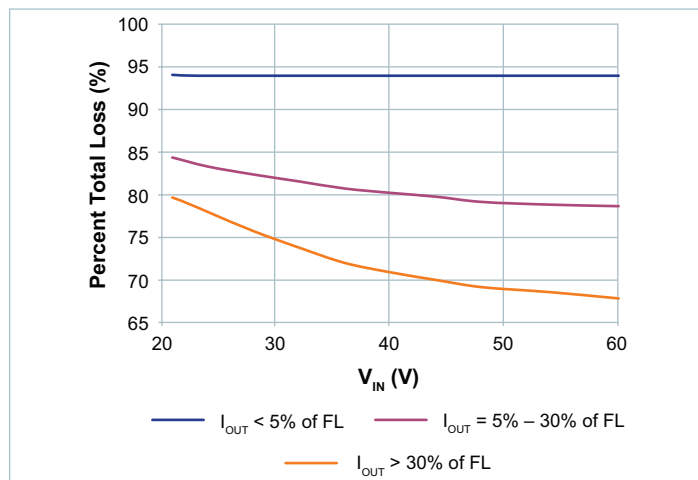
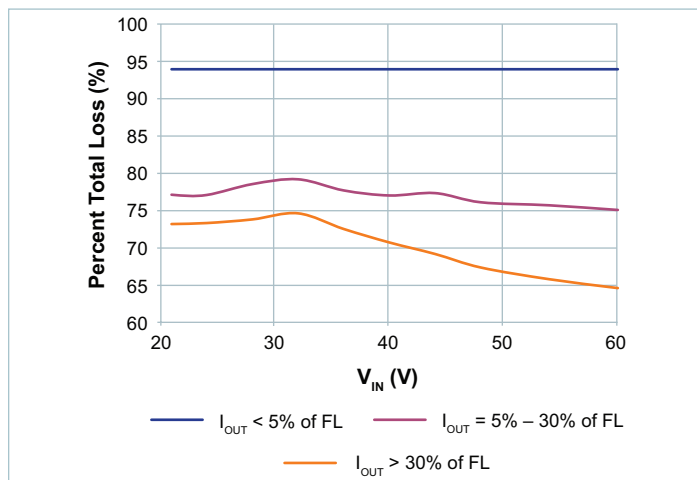
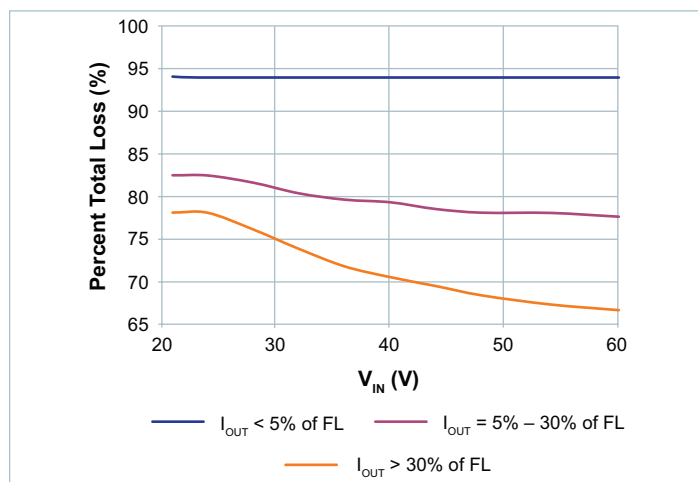
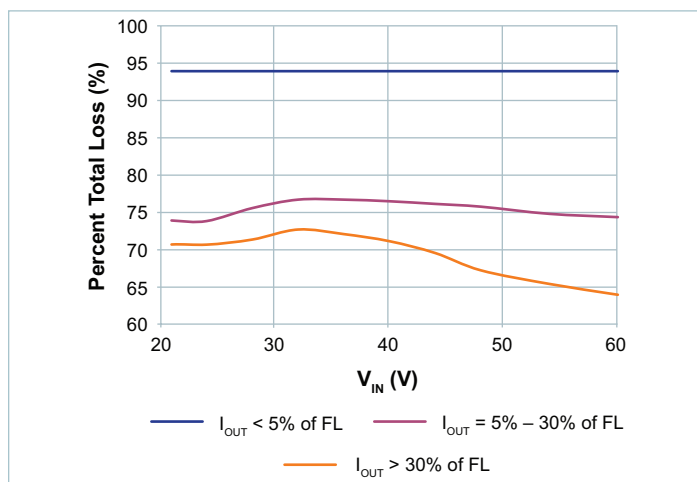
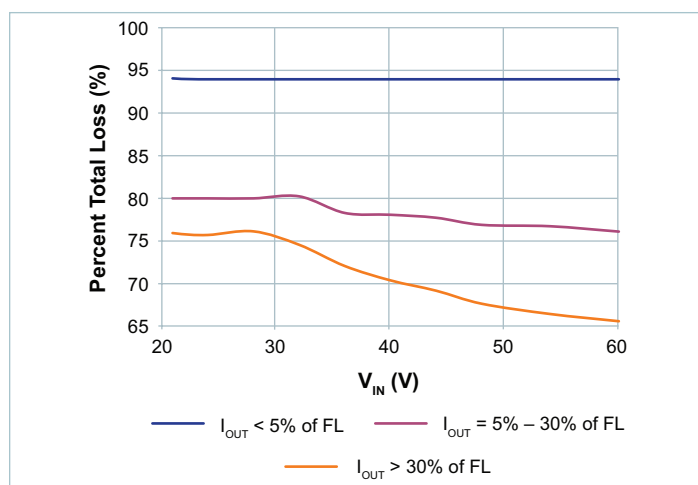
$$T_{HOTSPOT} = \frac{PD + \frac{T_{TOP}}{\theta_{INT-TOP}} + \frac{T_{PCB}}{\theta_{INT-PCB}}}{\frac{1}{\theta_{INT-TOP}} + \frac{1}{\theta_{INT-PCB}}} \quad (8)$$

Device	Thermal Impedance					Thermal Impedance with the simplified version		
	$\theta_{INT-TOP}$ (°C / W)	$\theta_{INT-BOT}$ (°C / W)	$\theta_{INT-TAB}$ (°C / W)	$\theta_{INT-LEAD1}$ (°C / W)	$\theta_{INT-LEAD2}$ (°C / W)	$\theta_{INT-TOP}$ (°C / W)	$\theta_{INT-BOT}$ (°C / W)	$\theta_{INT-PCB}$ (°C / W)
Inductor used with PI3741-00-LGIZ	16	21	250	43	43	16	21	20
Inductor used with PI3741-01-LGIZ	16	21	250	43	43	16	21	20

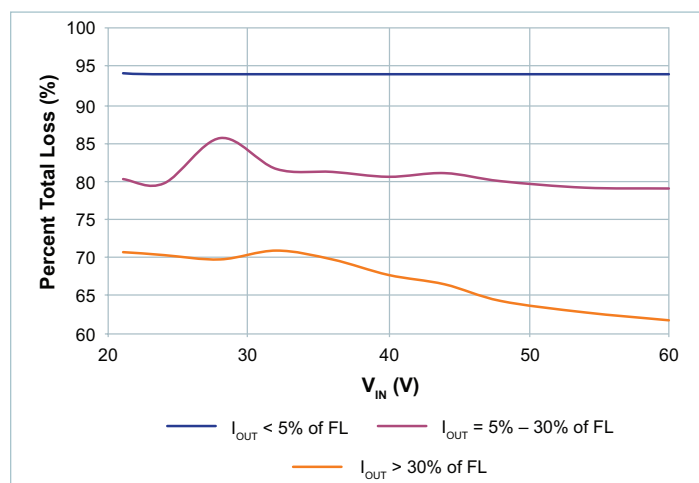
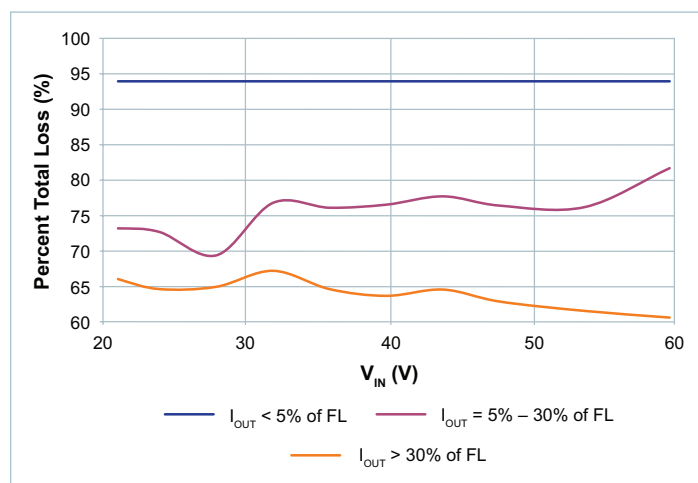
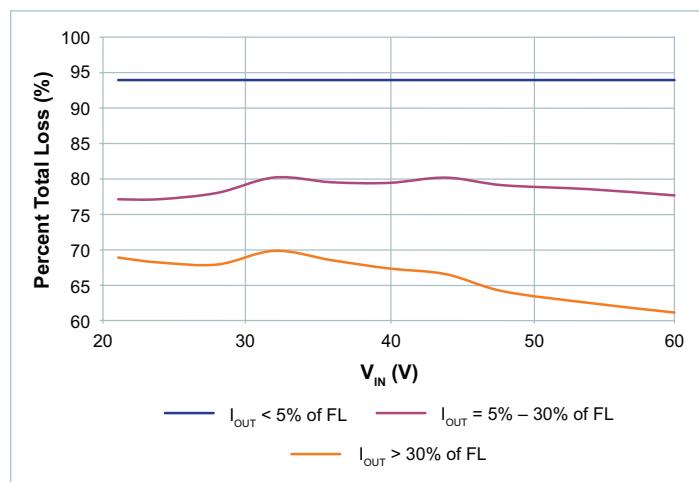
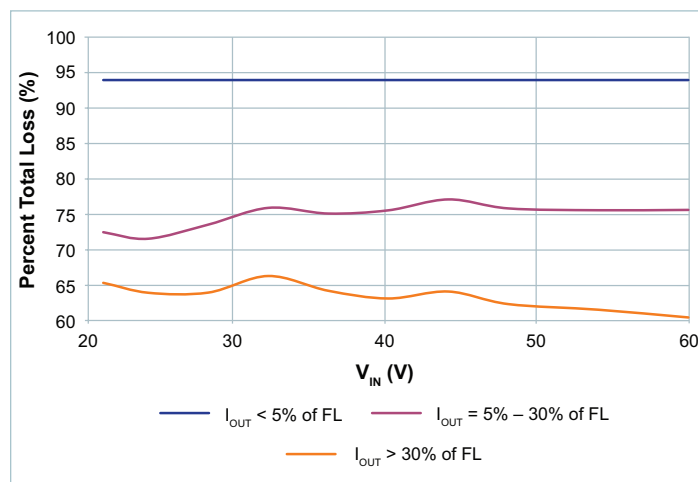
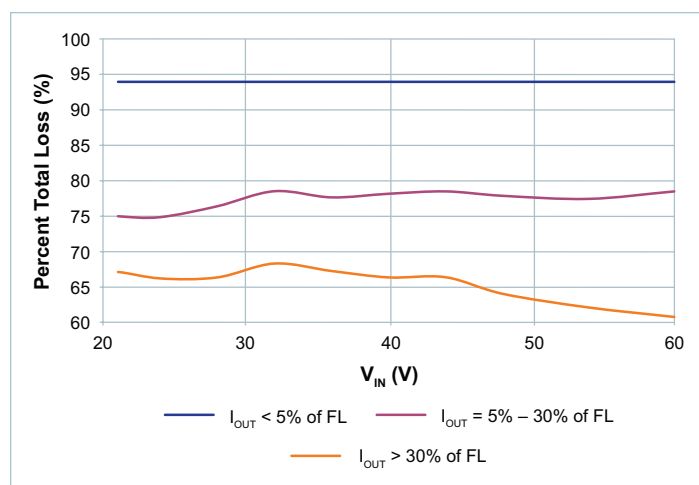
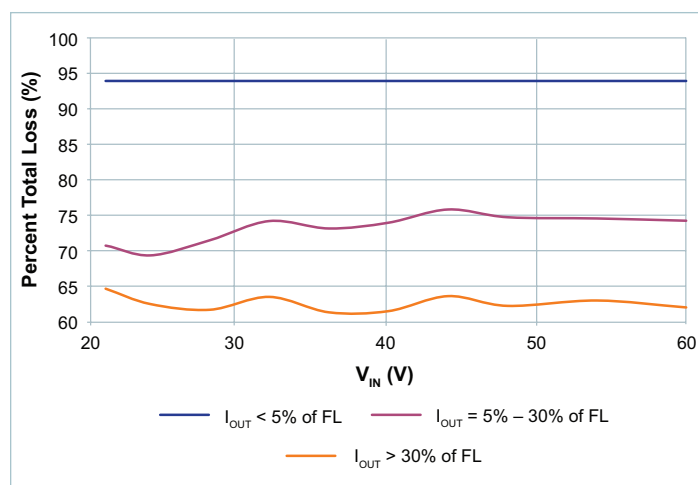
Table 5 — PI3741-0x Inductor Thermal Impedance

An estimation of SiP power loss to total loss percentage is shown in the following charts.

PI3741-00-LGIZ Percentage of SiP Loss to Total Loss

Figure 35 — $V_{OUT} = 21V$ Figure 38 — $V_{OUT} = 32V$ Figure 36 — $V_{OUT} = 24V$ Figure 39 — $V_{OUT} = 36V$ Figure 37 — $V_{OUT} = 28V$

PI3741-01-LGIZ Percentage of SiP Loss to Total Loss

Figure 40 — $V_{OUT} = 36V$ Figure 43 — $V_{OUT} = 48V$ Figure 41 — $V_{OUT} = 40V$ Figure 44 — $V_{OUT} = 50V$ Figure 42 — $V_{OUT} = 44V$ Figure 45 — $V_{OUT} = 54V$

Evaluation Board Thermal De-rating

Thermal de-rating curves are provided that are based on component temperature changes versus load current, input voltage and no air flow. It is recommended to use these curves as a guideline for proper thermal de-rating. These curves represent the entire system and are inclusive to both the Vicor SiP and the external inductor. Maximum thermal operation is limited by either the MOSFETs or inductor depending upon line and load conditions.

All thermal testing was performed using a 3in. x 3in., four 2oz. copper layers, FR4 evaluation board platform. Thermal measurements were made on the four internal MOSFETs and the external inductor.

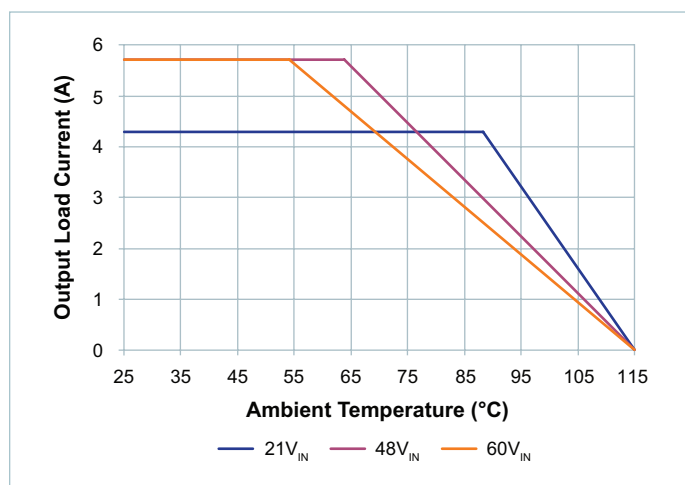


Figure 46 — Thermal de-rating for PI3741-00 evaluation board at $V_{OUT} = 21V$, 0LFM

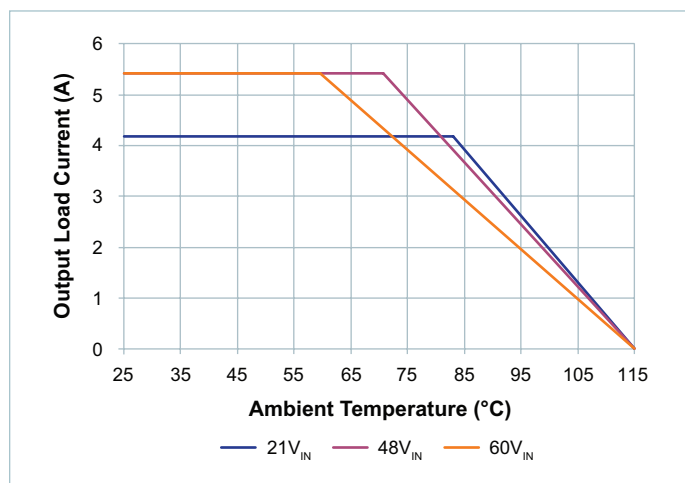


Figure 47 — Thermal de-rating PI3741-00 evaluation board at $V_{OUT} = 24V$, 0LFM

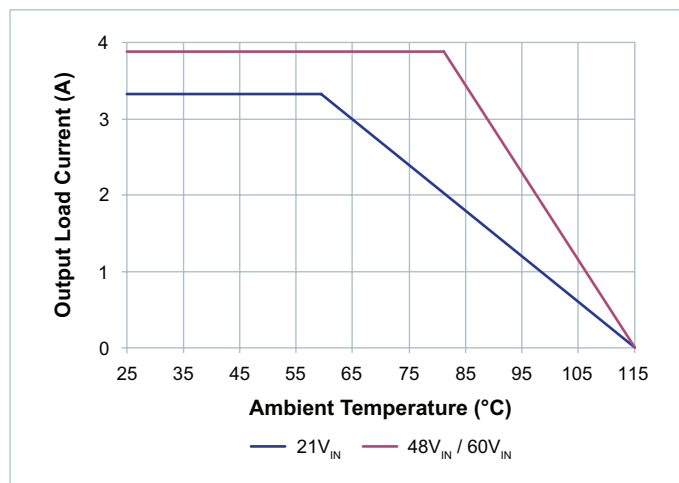


Figure 48 — Thermal de-rating for PI3741-00 evaluation board at $V_{OUT} = 36V$, 0LFM

Evaluation Board Thermal De-rating (Cont.)

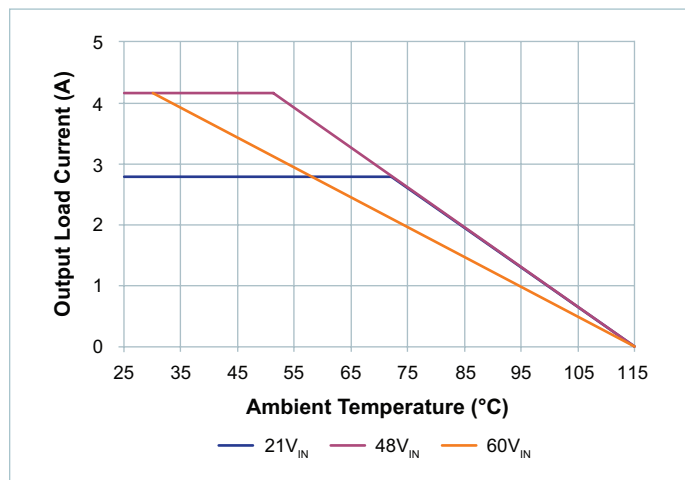


Figure 49 — Thermal de-rating for PI3741-01 evaluation board at $V_{OUT} = 36V, 0LFM$

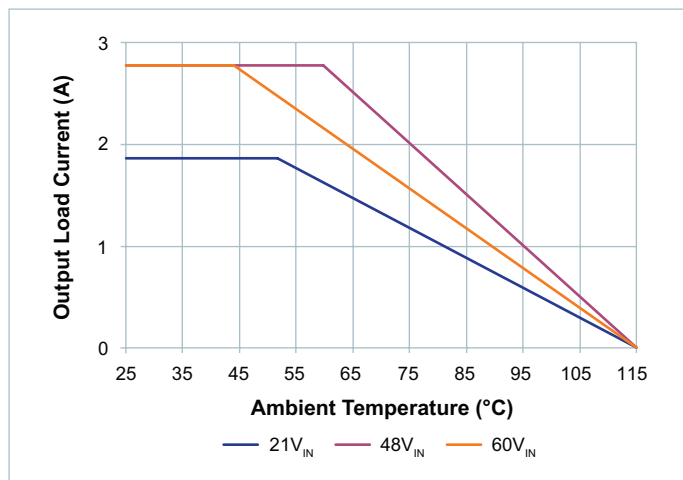


Figure 51 — Thermal de-rating for PI3741-01 evaluation board at $V_{OUT} = 54V, 0LFM$

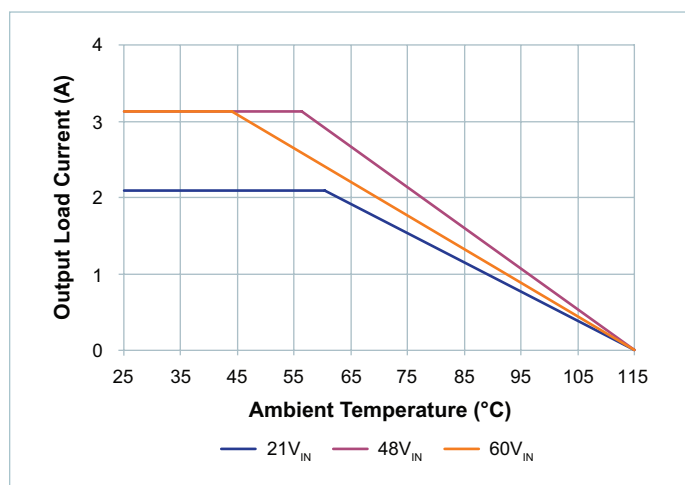


Figure 50 — Thermal de-rating PI3741-01 evaluation board at $V_{OUT} = 48V, 0LFM$

VDR Bias Regulator

The VDR internal bias regulator is a ZVS switching regulator that resides internal to the PI3741-0x. It is intended strictly for use to power the internal controller and driver circuitry. The power capability of this regulator is sized only for the PI3741-0x, with adequate reserve for the application it was intended for. It may be used for as a pull-up source for open collector applications and for other very low power use with the following restrictions:

- No direct connection is allowed. Any noise source that can disturb the VDR voltage can also affect the internal controller operation.
- All loads must be locally de-coupled using a 0.1 μ F ceramic capacitor. This capacitor must be connected to the VDR output through a series resistor no smaller than 1k Ω which forms a loss pass filter and limits the total current to 5mA.

System Design Considerations

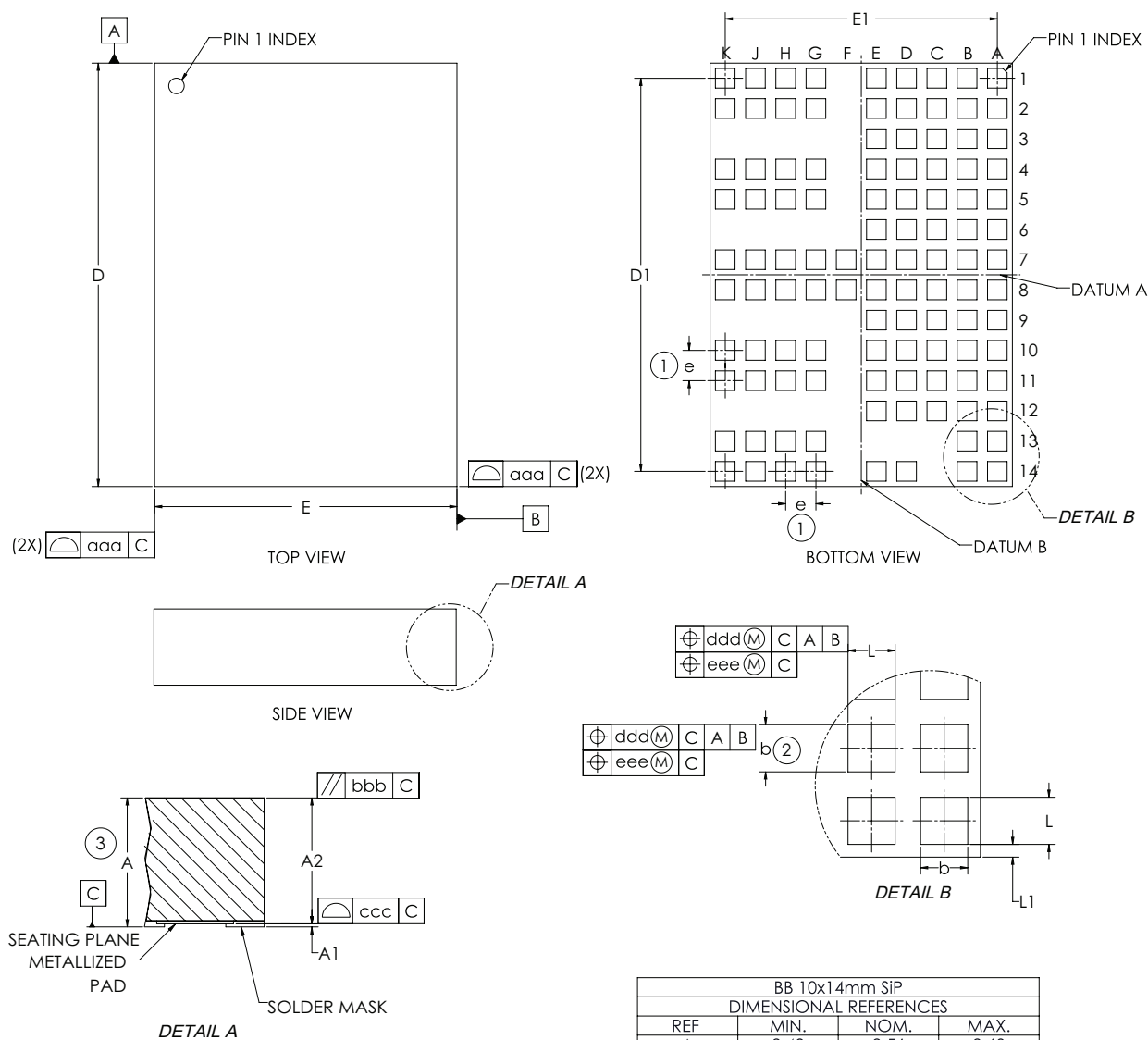
Inductive Loads

As with all power electronic applications, consideration must be given to driving inductive loads that may be exposed to a fault in the system which could result in consequences beyond the scope of the power supply primary protection mechanisms. An inductive load could be a filter, fan motor or even excessively long cables. Consider an instantaneous short circuit through an un-damped inductance that occurs when the output capacitors are already at an initial condition of fully charged. The only thing that limits the current is the inductance of the short circuit and any series resistance. Even if the power supply is off at the time of the short circuit, the current could ramp up in the external inductor and store considerable energy. The release of this energy will result in considerable ringing, with the possibility of ringing nodes connected to the output voltage below ground. The system designer should plan for this by considering the use of other external circuit protection such as load switches, fuses, and transient voltage protectors. The inductive filters should be critically damped to avoid excessive ringing or damaging voltages. Adding a high current Schottky diode from the output voltage to PGND close to the PI741-0x is recommended for these applications.

Low Voltage Operation

There is no isolation from an SELV (Safety-Extra-Low-Voltage) power system. Powering low voltage loads from input voltages as high as 60V may require additional consideration to protect low voltage circuits from excessive voltage in the event of a short circuit from input to output. A fast TVS (transient voltage suppressor) gating an external load switch is an example of such protection.

Package Drawings



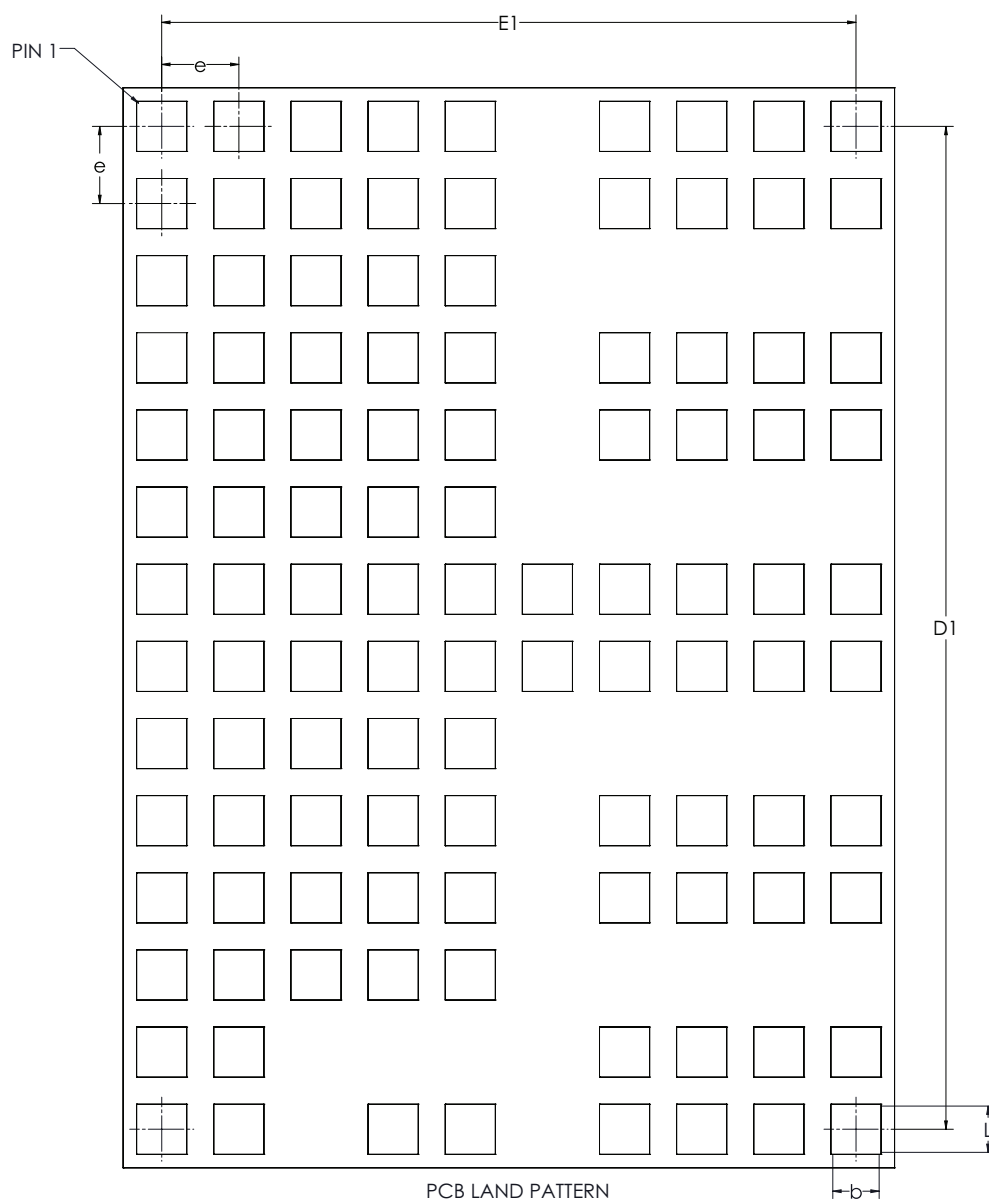
BB 10x14mm SiP	
DIMENSIONAL REFERENCES	
REF.	TOLERANCE OF FORM AND POSITION
aaa	0.10
bbb	0.10
ccc	0.08
ddd	0.10
eee	0.08

BB 10x14mm SiP			
DIMENSIONAL REFERENCES			
REF.	MIN.	NOM.	MAX.
A	2.49	2.56	2.63
A1	--	--	0.04
A2	--	--	2.59
b	0.50	0.55	0.60
L	0.50	0.55	0.60
D	14.00 BSC		
E	10.00 BSC		
D1	13.00 BSC		
E1	9.00 BSC		
e	1.00 BSC		
L1	.175	0.225	.275

NOTES:

1. 'e' REPRESENTS THE BASIC TERMINAL PITCH. SPECIFIES THE GEOMETRIC POSITION OF THE TERMINAL AXIS.
2. DIMENSION 'b' APPLIES TO METALLIZED TERMINAL AND IS MEASURED BETWEEN 0.00mm AND 0.25mm FROM TERMINAL TIP.
3. DIMENSION 'A' INCLUDES PACKAGE WARPAGE.
4. EXPOSED METALLIZED PADS ARE CU PADS WITH SURFACE FINISH PROTECTION.
5. ALL DIMENSIONS ARE IN MM UNLESS OTHERWISE SPECIFIED.
6. RoHS COMPLIANT PER CST-0001 LATEST REVISION.

Receiving PCB Pattern Design Recommendations



DIMENSIONAL REFERENCES			
REF.	MIN.	NOM.	MAX.
b	0.50	0.55	0.60
D1	13.00 BSC		
E1	9.00 BSC		
e	1.00 BSC		
L	0.50	0.55	0.60

Recommended receiving footprint for PI3741-0x 10mm x 14mm package. All pads should have a final copper size of 0.55mm x 0.55mm, whether they are solder-mask defined or copper defined, on a 1mm x 1mm grid. All stencil openings are 0.45mm when using either a 5mil or 6mil stencil.

Revision History

Revision	Date	Description	Page Number(s)
1.0	08/29/16	Initial Release	n/a
1.1	08/31/16	Update package drawings	6, 35, 36
1.2	02/08/17	Corrections to Typical Application, Figure 30 Update package outline drawings	1, 21 6, 35, 36
1.3	03/10/17	Miscellaneous typo corrections	2, 8, 11
1.4	03/31/17	Correct LGH pin name Include additional PCB Pattern information	6 36
1.5	05/31/17	Update Absolute Maximum Ratings Update IMON Output voltage specification	4 8
1.6	06/14/17	Parallel Operation update	33
1.7	08/24/17	Updated tables 4 and 5, inductor thermal impedance model	27-28
1.8	02/22/18	Updated output specifications Updated figure descriptions	8, 11 16, 19
1.9	02/27/20	Rounded thermal impedance values to two significant figures Updated LGA package drawings	27, 29 36, 37
2.0	08/12/20	Updated terminology	23

Please note: Page added in Rev 1.7.

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Vicor Corporation
25 Frontage Road
Andover, MA, USA 01810
Tel: 800-735-6200
Fax: 978-475-6715
www.vicorpower.com

email

Customer Service: custserv@vicorpower.com
Technical Support: apps@vicorpower.com

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